



Electronics – 96032

 POLITECNICO DI MILANO



# Instrumentation Amps and OA Parameters

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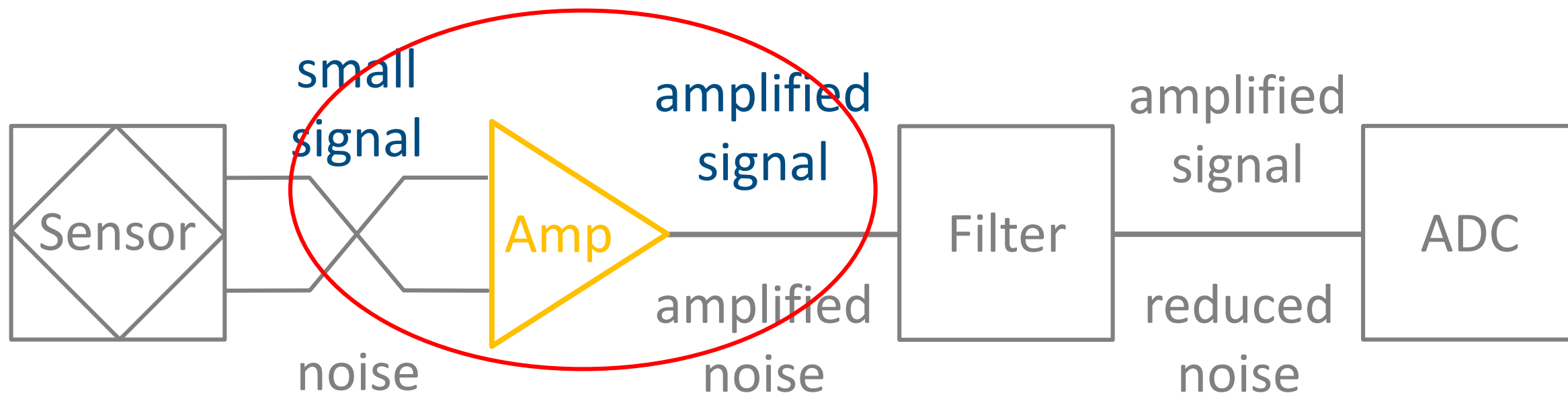


Slides are supplementary material and are NOT a replacement for textbooks and/or lecture notes



# Acquisition chain

3



next lessons



# Purpose of the lesson

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- We begin our study with the analysis and design of simple amplifiers
- Next lessons will deal with
  - Basic amplifier principles and the feedback amplifier concept
  - Linear applications of OpAmps
  - Feedback amplifier properties
  - Stability of feedback amplifiers
  - Instrumentation amplifiers and OpAmp parameters (this lesson)

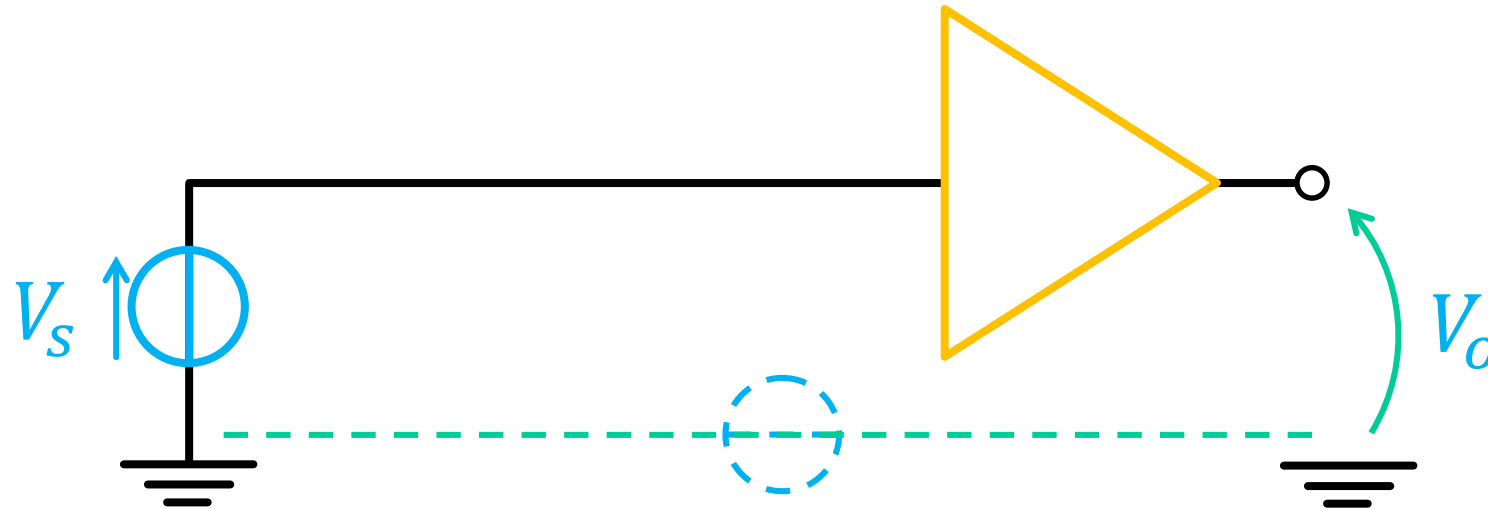


- Differential signals and CMRR
- Instrumentation amplifiers
- Other OA limitations
- Circuit simulation with Simulink
- Appendix 1: Single-supply OA circuits
- Appendix 2: OA datasheets



# Single-ended signals

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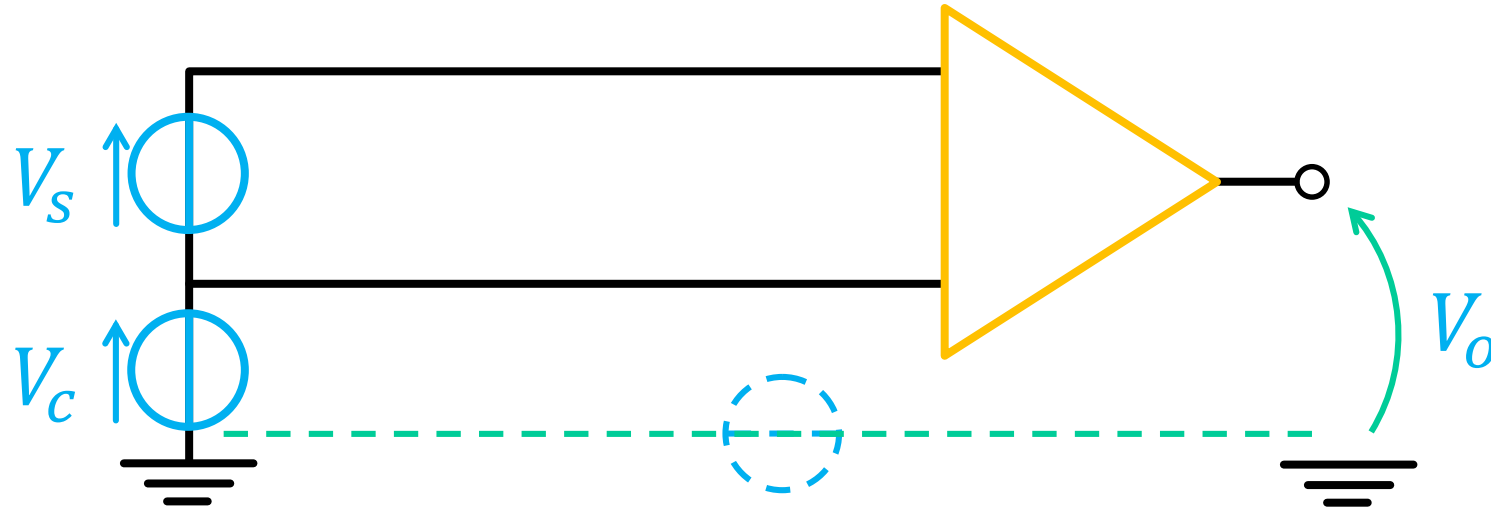


- Simple setup
- Sensitive to noise/interferences
- Sensitive to differences in ground potentials



# Differential signals

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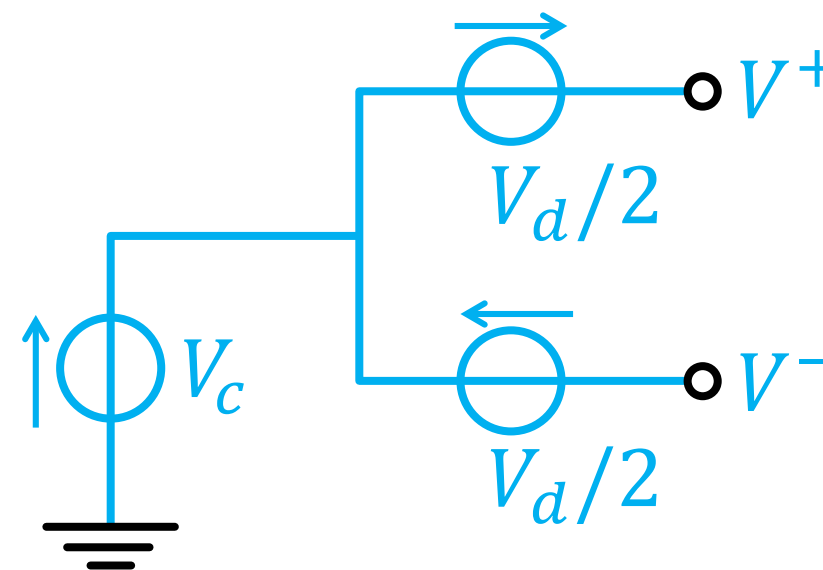
- Higher immunity to noise and disturbs
- Amplifier needs to reject common-mode signal/noise (incl. ground potential fluctuations)
- Can be more expensive



# Common and differential modes

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- Given the input voltages  $V^+$  and  $V^-$ , we define
  - Common-mode voltage  $V_c = \frac{V^+ + V^-}{2}$
  - Differential-mode voltage  $V_d = V^+ - V^-$





# Common mode rejection ratio

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- A generic amplifier output can be written as

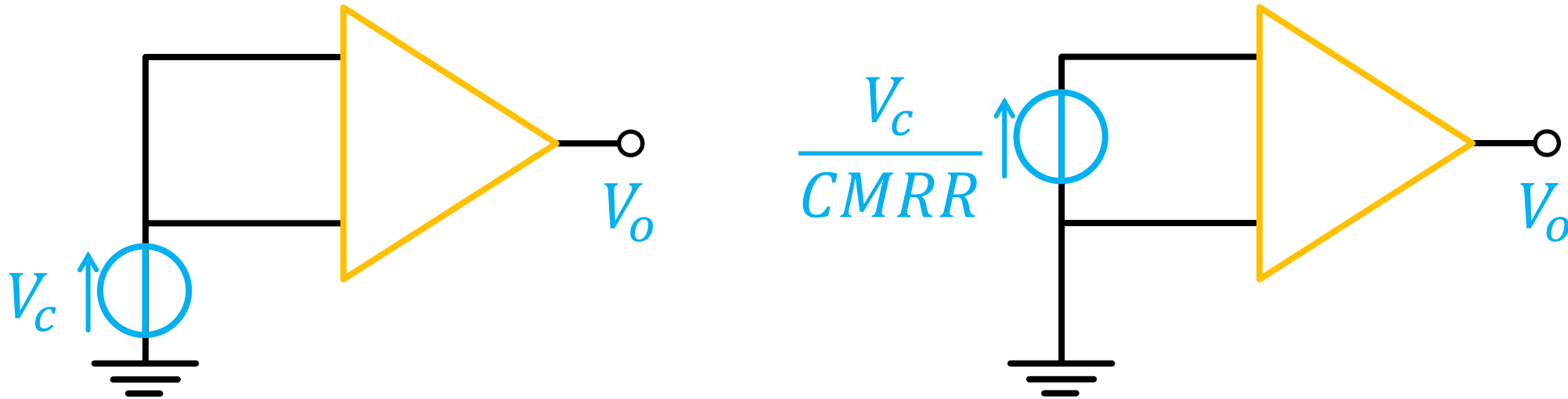
$$V_o = A_d V_d + A_c V_c = A_d \left( V_d + \frac{V_c}{CMRR} \right)$$

where

$$CMRR = \frac{A_d}{A_c}$$

- To have small error

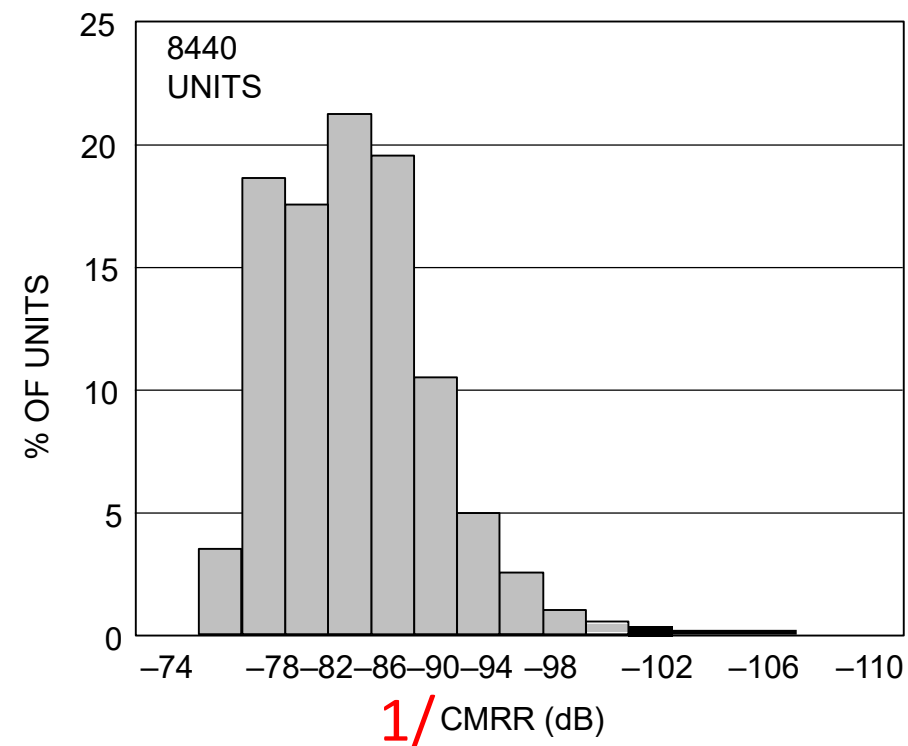
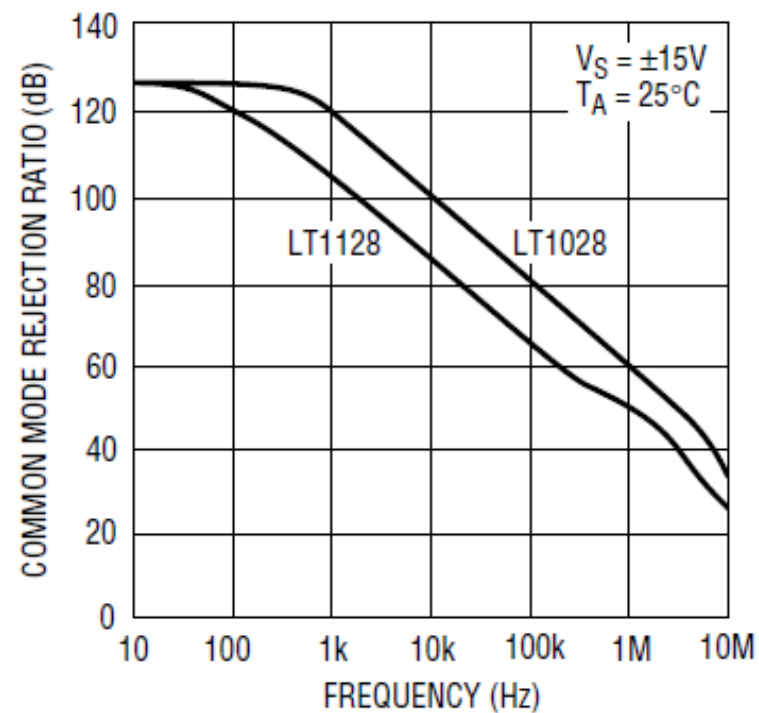
$$\frac{V_c}{CMRR} \ll V_d \Rightarrow CMRR \gg \frac{V_c}{V_d}$$



- CMRR converts the common-mode signal into an equivalent differential signal
- Typical values for OAs are 70 – 120 dB



# Actual values from datasheets

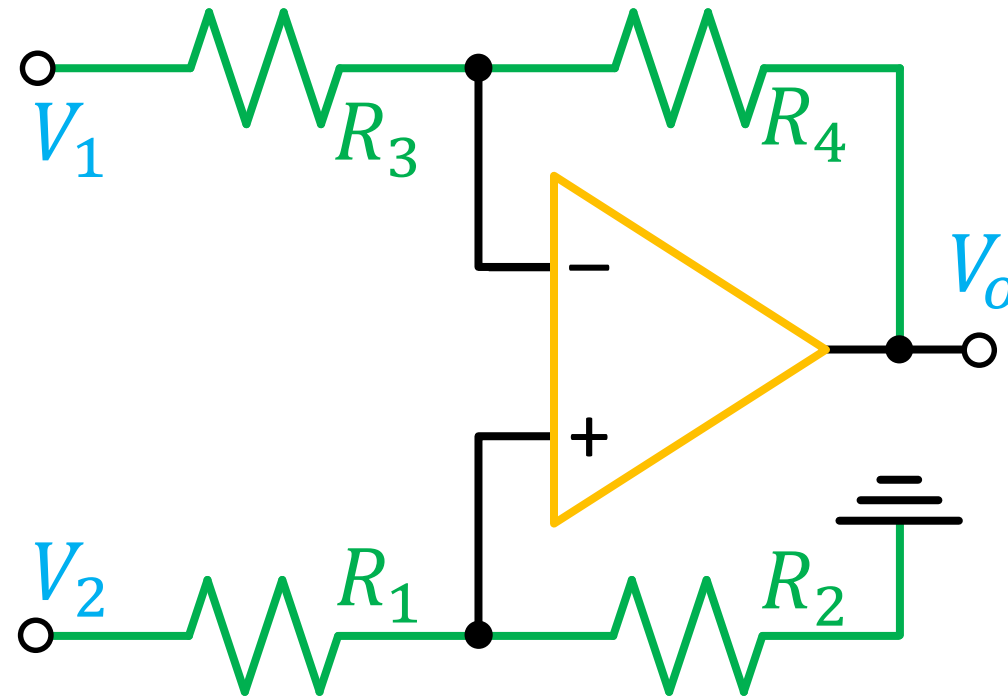


CMRR decreases with frequency



# Subtractor circuit

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- Easy to design
- Low and asymmetric  $Z_{in}$
- Actual  $CMRR$  is limited by resistor matching



- The common-mode gain can be expressed as

$$A_{cm} = -\frac{R_4}{R_3} + \frac{R_3 + R_4}{R_3} \frac{R_2}{R_1 + R_2} = \frac{1 - \frac{R_1}{R_2} \frac{R_4}{R_3}}{1 + R_1/R_2}$$

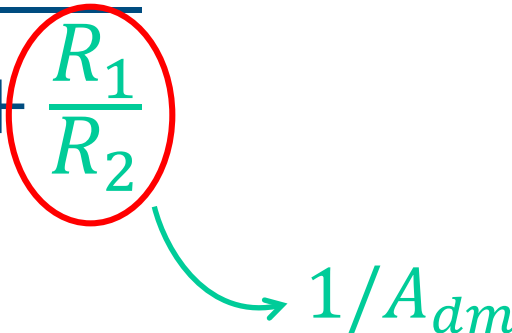
- Due to tolerances,  $R \rightarrow R \pm \Delta R = R(1 \pm x)$

$$\frac{R_1}{R_2} \rightarrow \frac{R_1(1 \pm x)}{R_2(1 \mp x)} \approx \frac{R_1}{R_2} (1 \pm x)^2 \approx \frac{R_1}{R_2} (1 \pm 2x)$$

$$\frac{R_3}{R_4} \rightarrow \frac{R_3}{R_4} (1 \pm 2x)$$



- Worst-case  $A_{cm}$  and  $CMRR$  become

$$A_{cm} = \frac{1 - \frac{R_1}{R_2} \frac{R_4}{R_3}}{1 + R_1/R_2} = \frac{1 - \frac{1 \pm 2x}{1 \mp 2x}}{1 + R_1/R_2} \approx \frac{4x}{1 + \frac{R_1}{R_2}}$$
$$CMRR = \frac{A_{dm} + 1}{4x}$$


- For discrete  $R$ ,  $x = 10\%$  (silver),  $5\%$  (gold), down to  $1\%$  (violet)
- For a subtractor with  $A_{dm} = 1$  and  $x = 0.1\%$ ,  $CMRR = 54$  dB

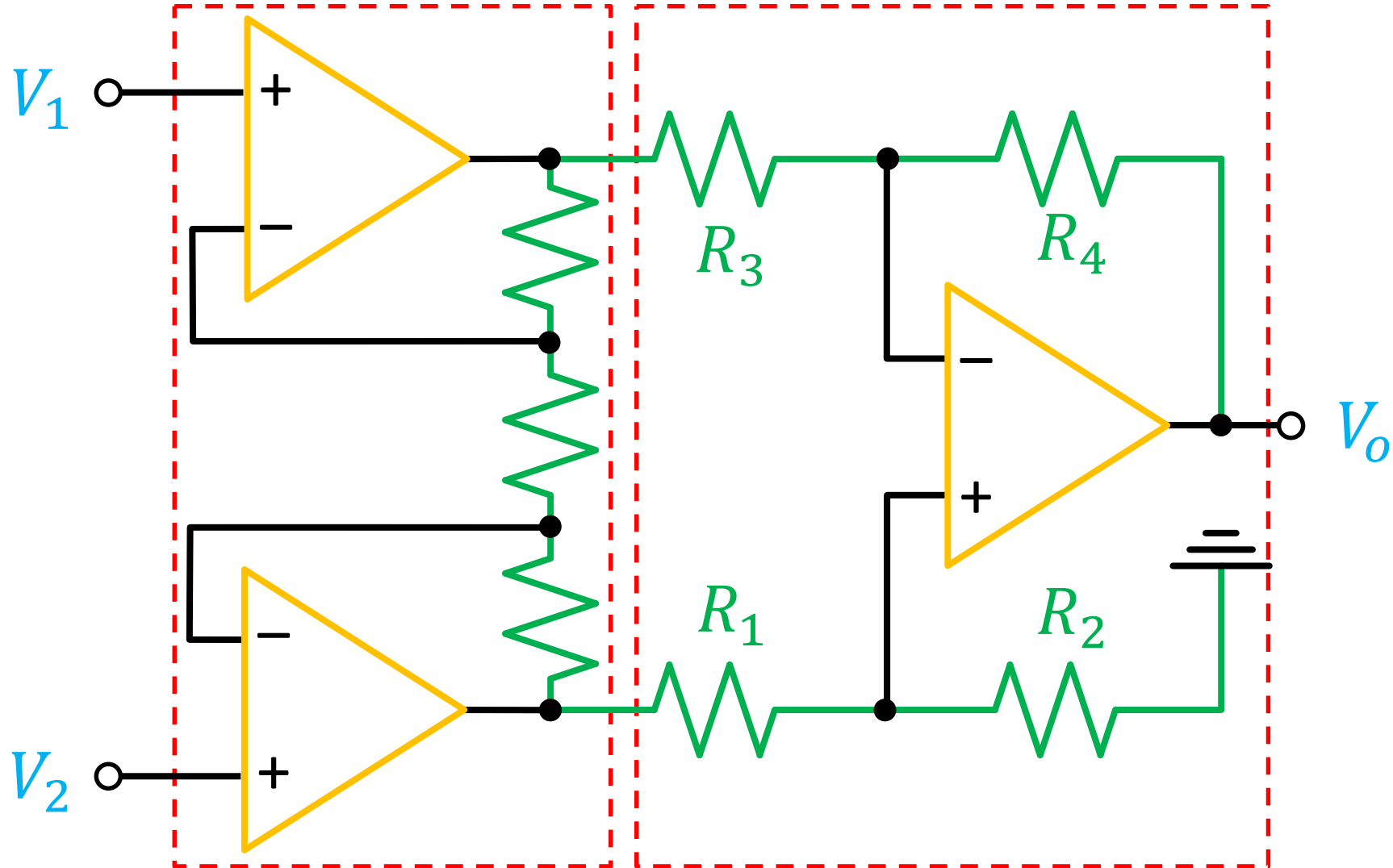


- Differential signals and CMRR
- **Instrumentation amplifiers**
- Other OA limitations
- Circuit simulation with Simulink
- Appendix 1: Single-supply OA circuits
- Appendix 2: OA datasheets



# The concept

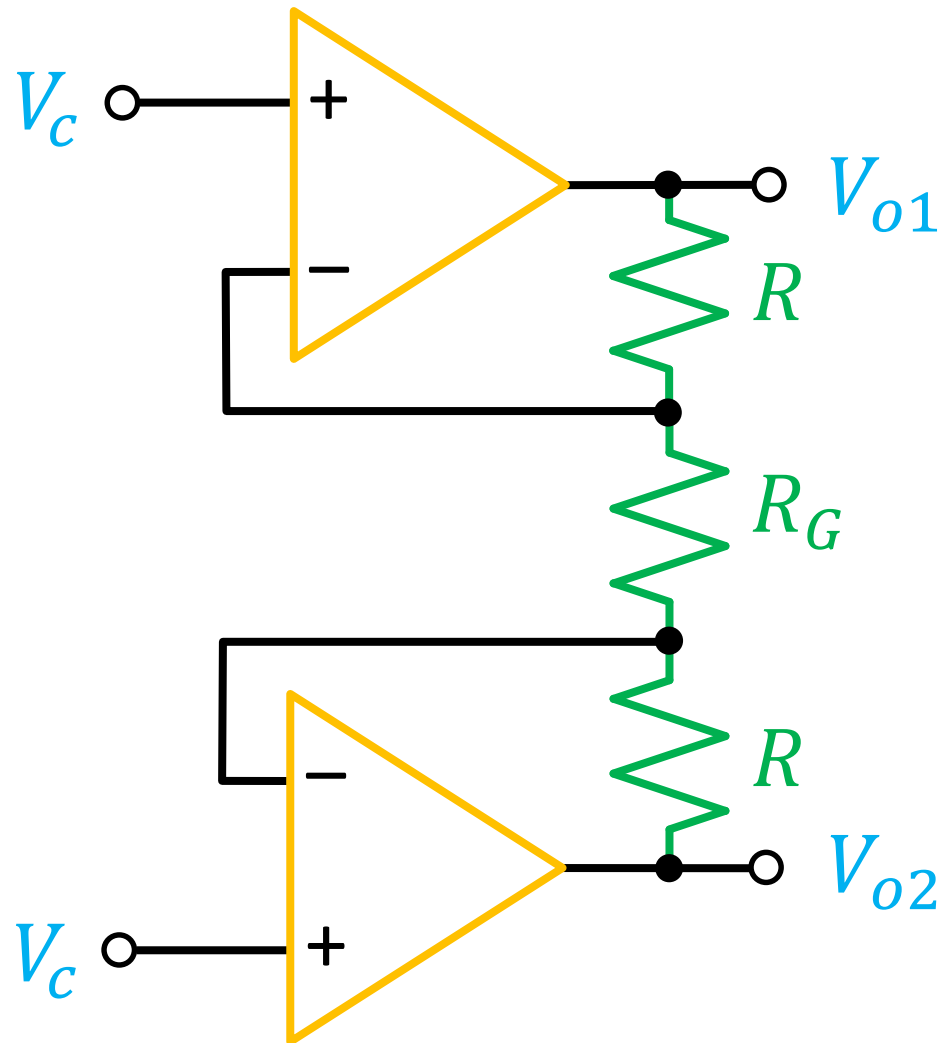
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# First stage – CM

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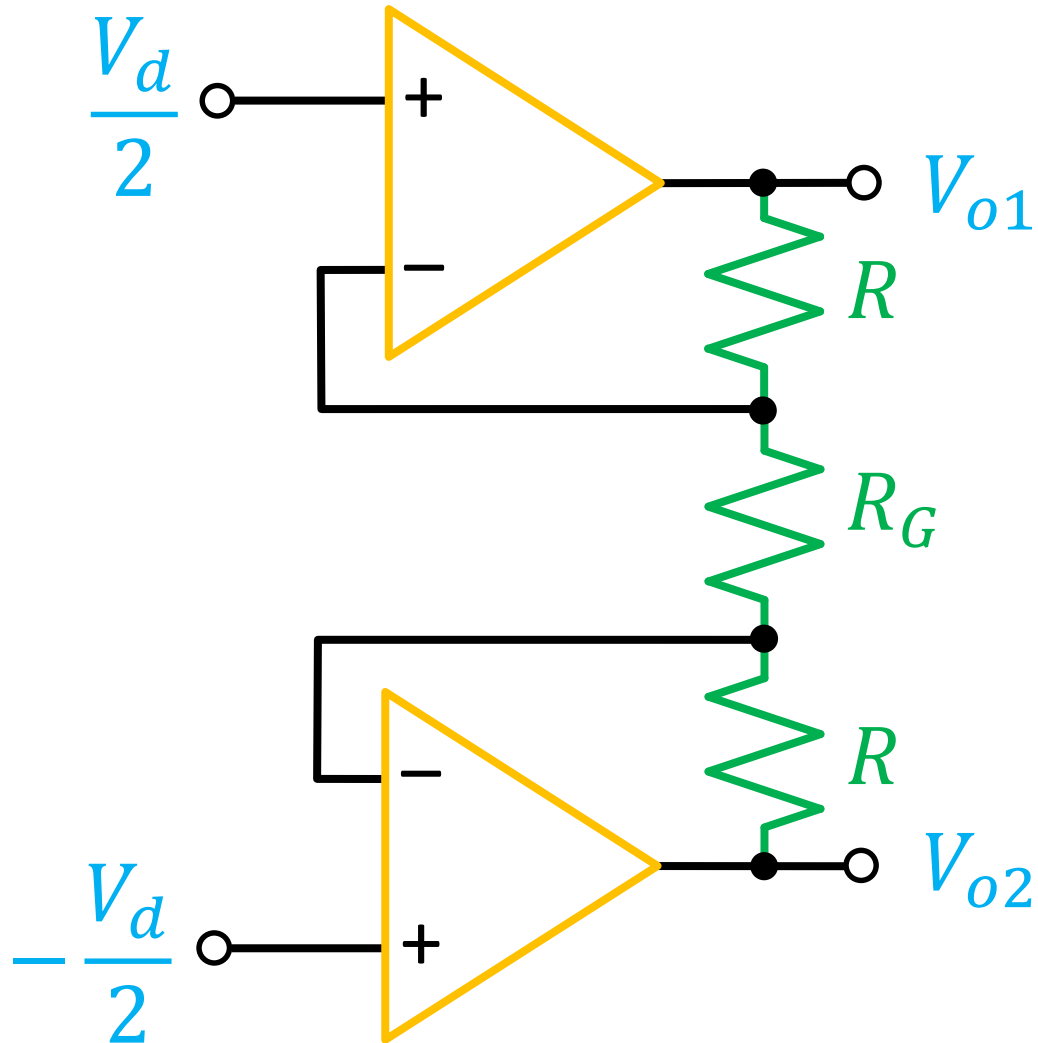
$$A_{cm1} = 1$$

Independent of  
resistor matching!



# First stage – DM

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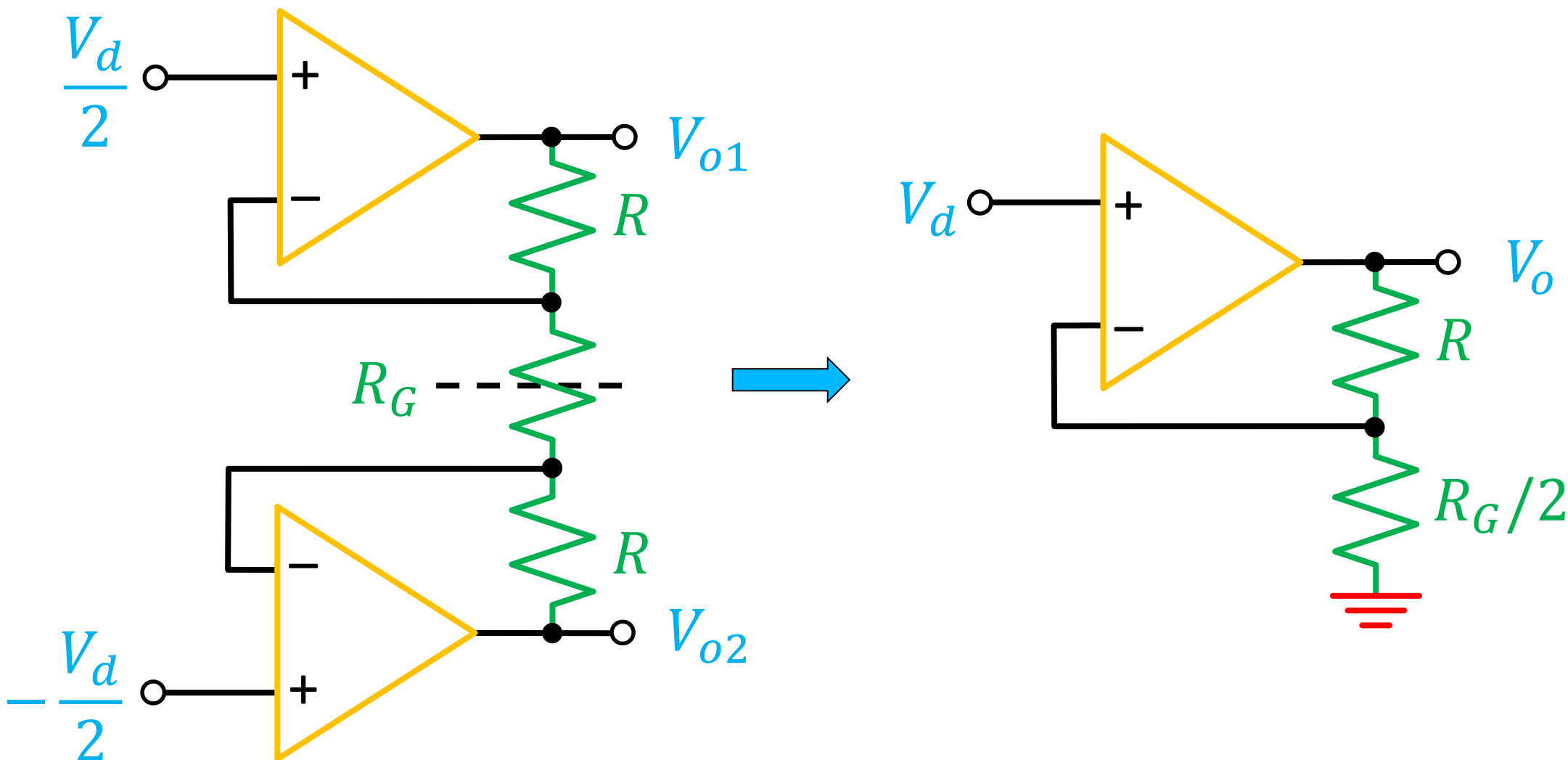
$$A_{dm1} = \frac{V_{o1} - V_{o2}}{V_d} = 1 + \frac{2R}{R_G}$$

Set by the external resistor  $R_G$



# Half-circuit approach

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$$CMRR = \frac{A_{dm}}{A_{cm}} = \frac{A_{dm1}A_{dm2}}{A_{cm1}A_{cm2}} = A_{dm1}CMRR_2$$

- $CMRR$  is actually limited by the OAs
- To a first approximation, CM errors will be cancelled by the second stage  $\Rightarrow$  it is the difference in OA  $CMRR$ s that counts!
- Can achieve  $CMRR$  of 90 – 140 dB



- Gain range (e.g., 1 – 1000): the range in which device is guaranteed to work as specified
- Gain (or equation) error (e.g., 0.5%): maximum deviation from the gain equation (tolerances in  $R$ , serie resistances,...)
- Nonlinearity (e.g., 100ppm): maximum deviation from interpolating line
- Offset voltage:  $V_{OS} = V_{OS1} + \frac{V_{OS2}}{G}$



# Typical parameters

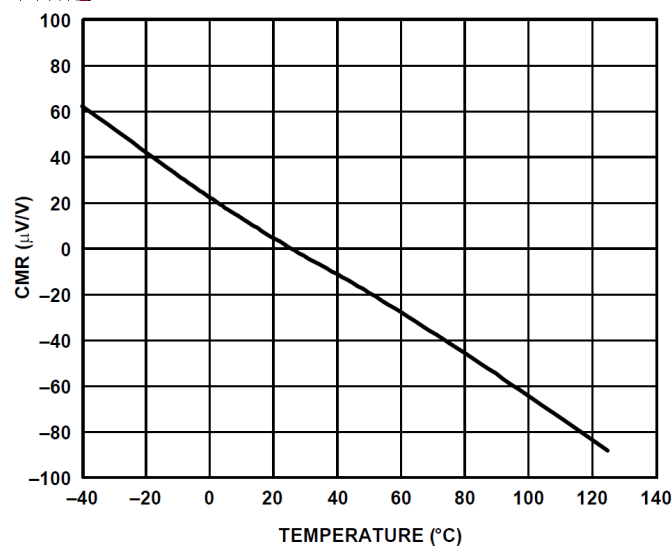
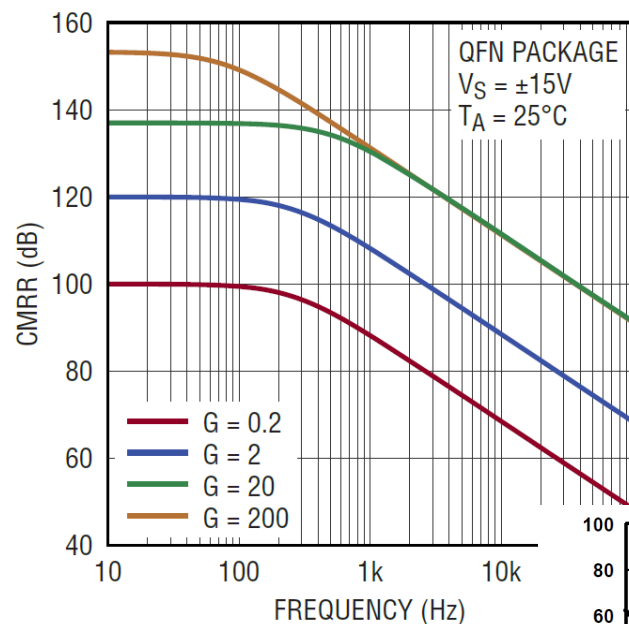
22

- $GBWP \approx 100 \text{ kHz}$
- $V_{OS} < 500 \text{ } \mu\text{V}$ , drift  $< 0.5 \text{ } \mu\text{V}/^\circ\text{C}$
- $I_B < 2 \text{ nA}$
- Usually made with bipolar technology

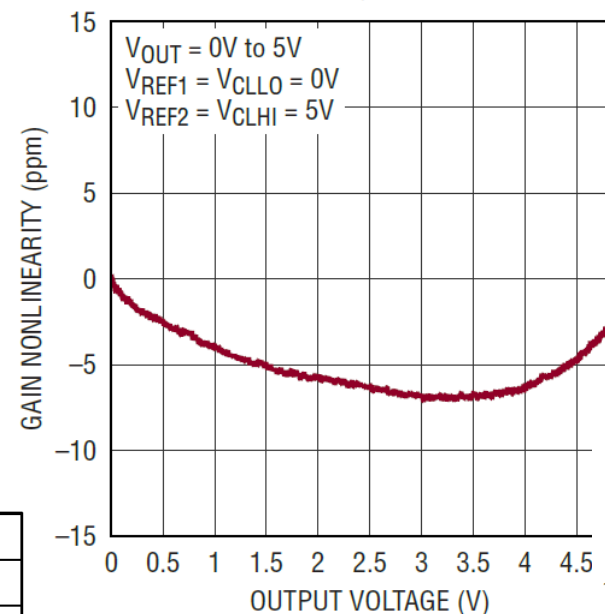


# Datasheet parameters

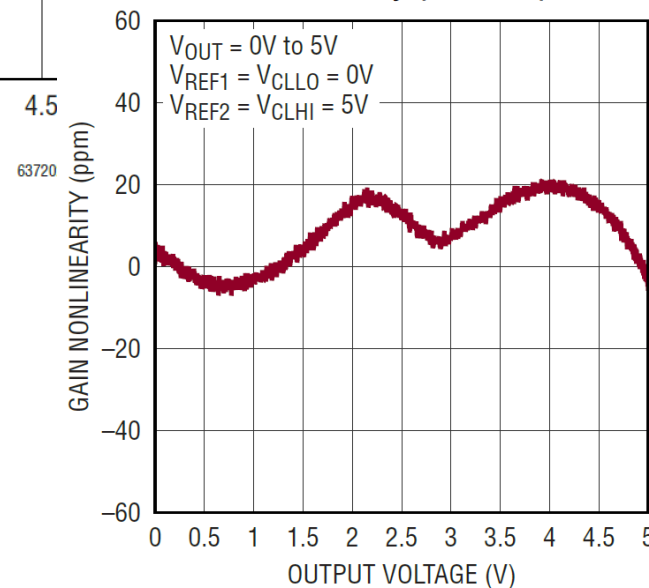
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Gain Nonlinearity ( $G = 0.2$ )



Gain Nonlinearity ( $G = 200$ )





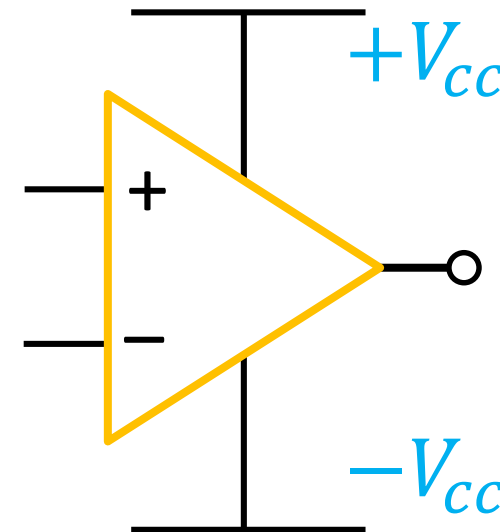
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# Supply voltage

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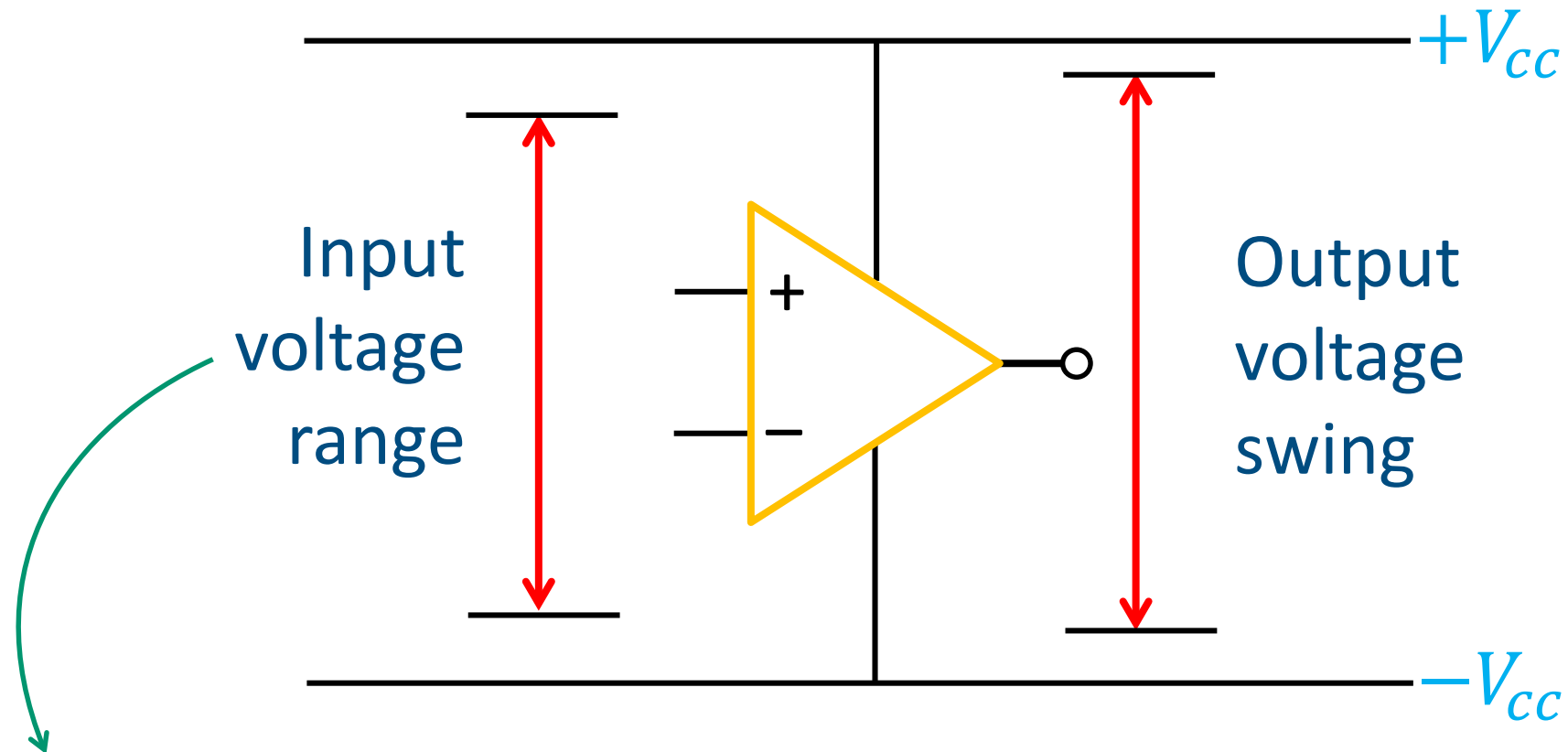
- Dual symmetrical power supply is almost always used
- $V_{cc}$  must be kept within a specified range (see Appendix 2)





# OA parameter: I/O voltage ranges/swings

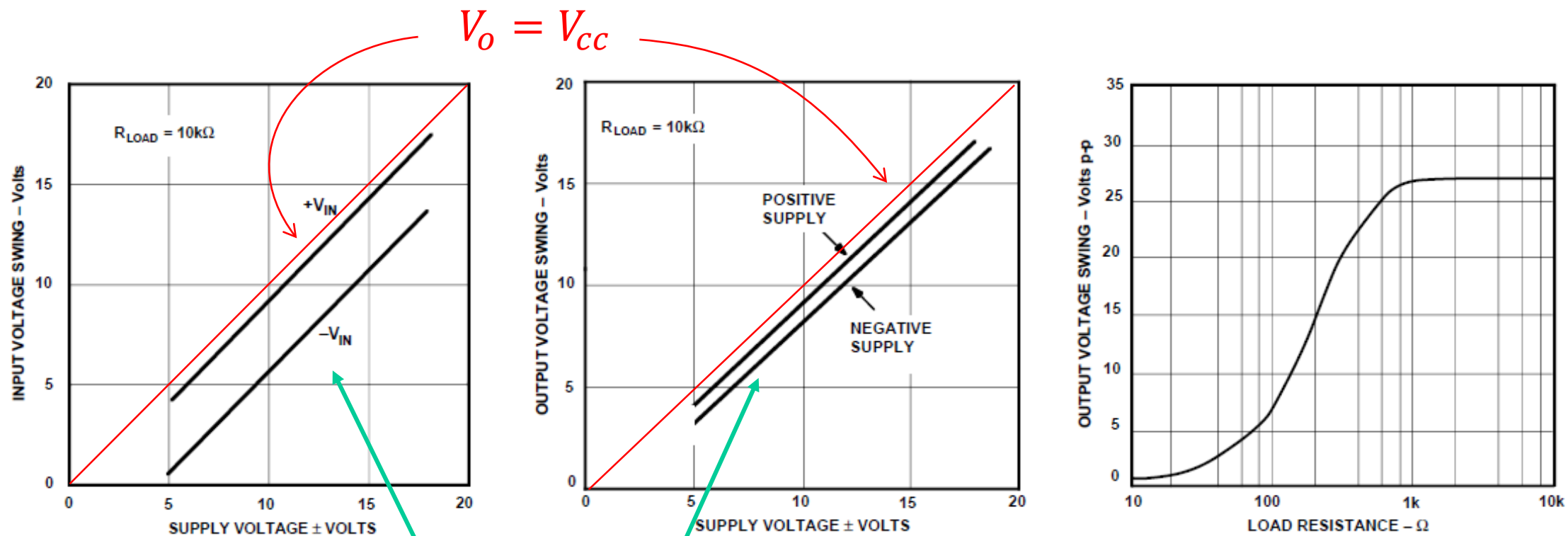
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A common-mode input range is also defined, related to  $(V^+ + V^-)/2$



# Actual values from datasheets



Dependence on  $R_L$   
(i.e., on delivered  
current)

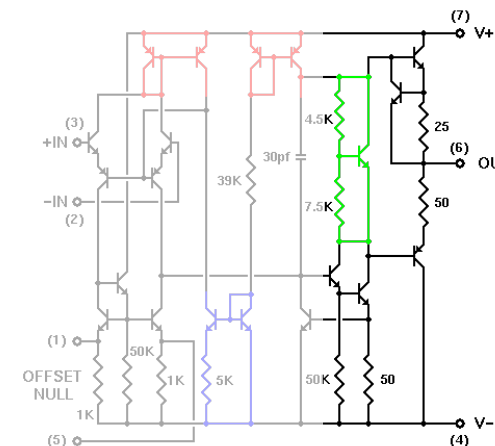
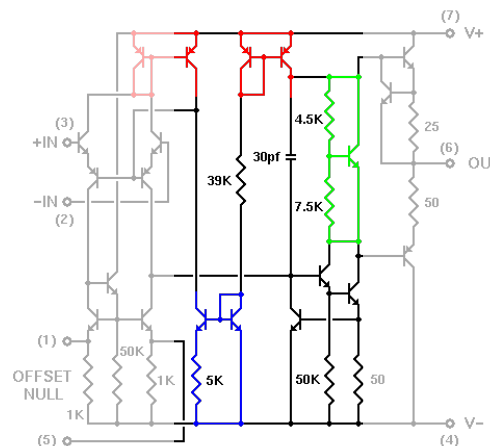
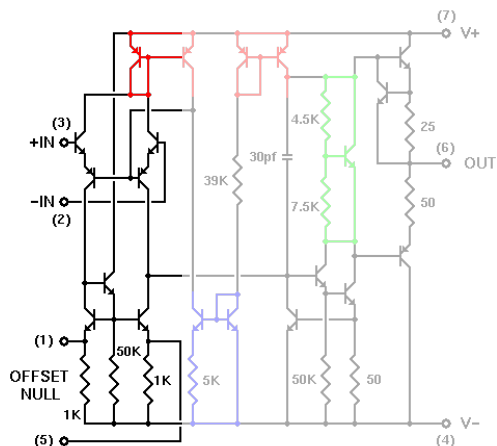
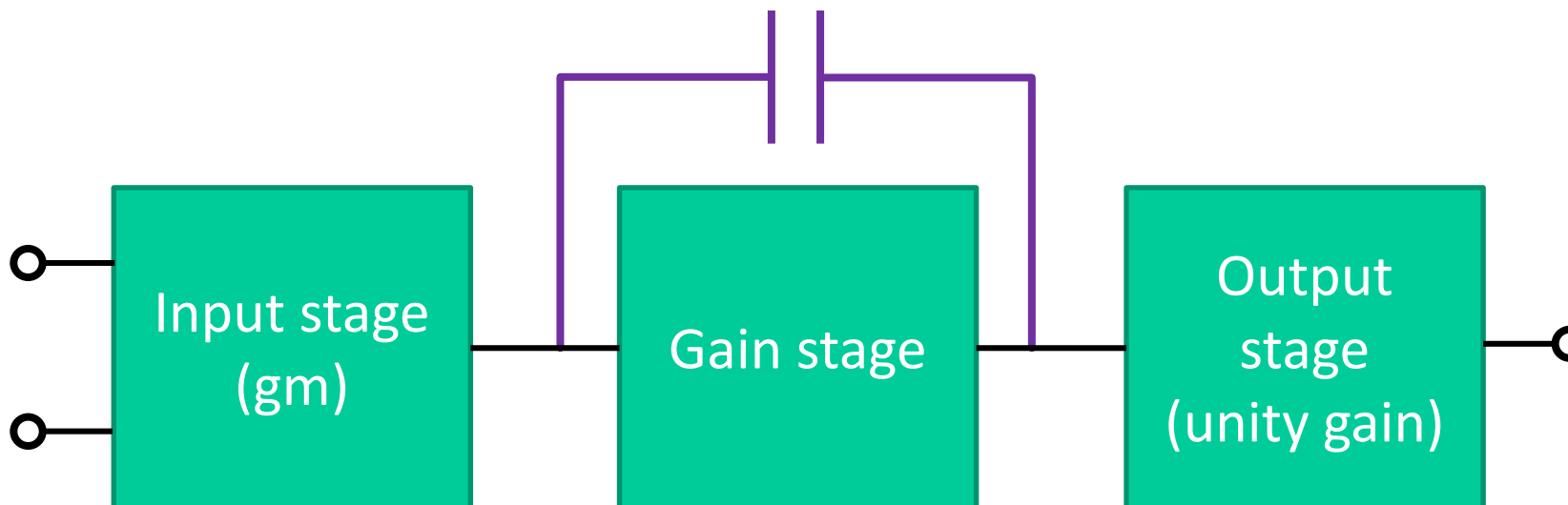


- Up to here, we always implicitly considered dual power supply,  $\pm V_{CC}$
- In reality, single-supply design ( $+V_{CC}, 0$ ) is often needed:
  - Adopt power sources already available (e.g., 5 V logic rail)
  - Can be powered with batteries
  - Reduce costs
- Circuits must be redesigned to work with single supply (see Appendix 1)



# Internal circuit (block scheme)

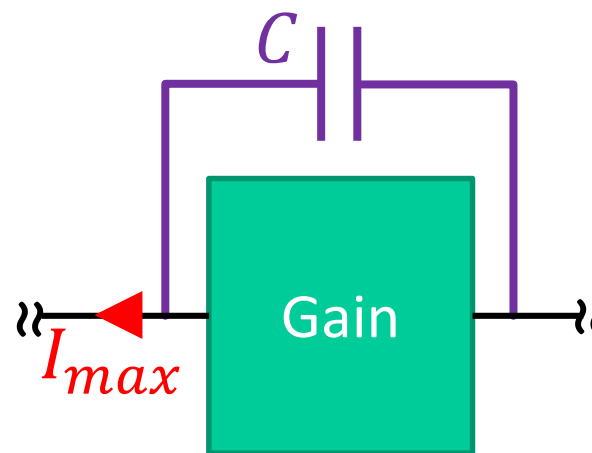
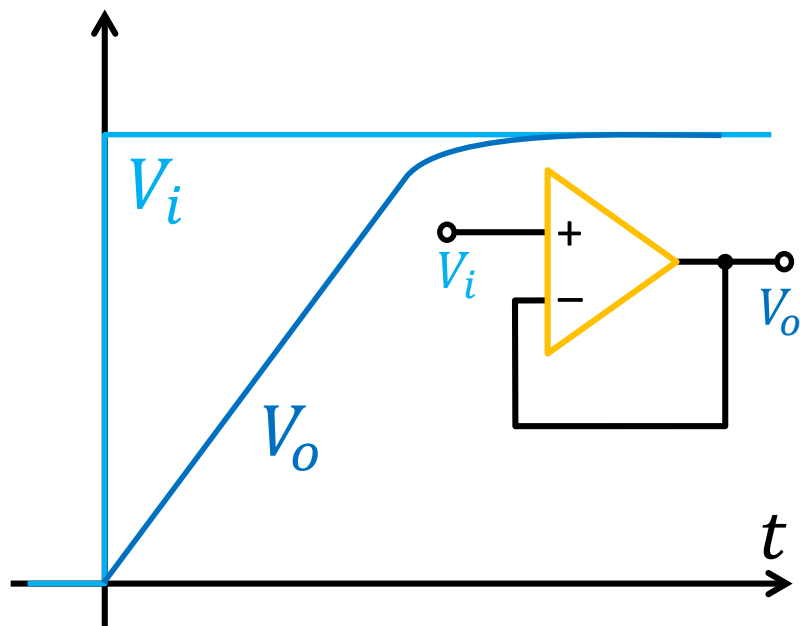
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# Slew rate

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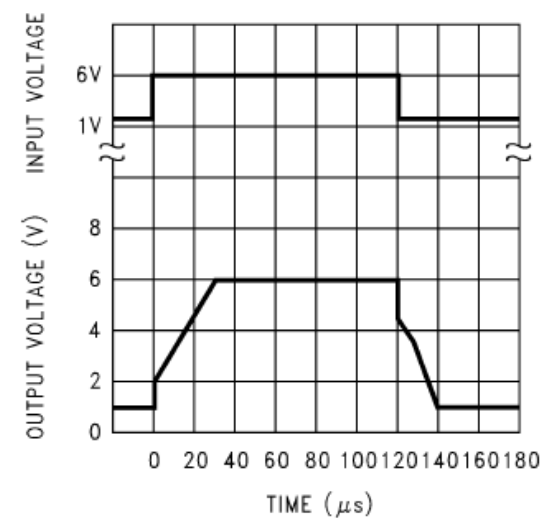
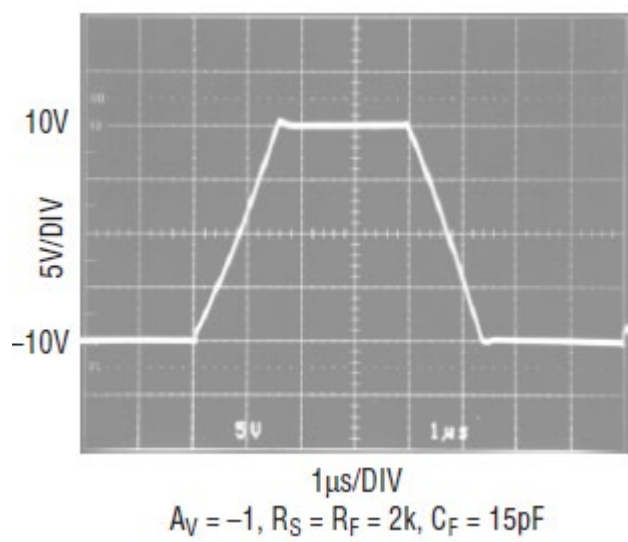
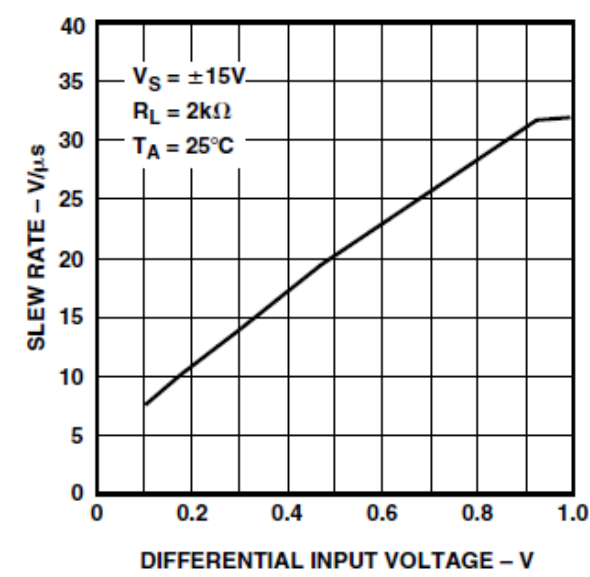
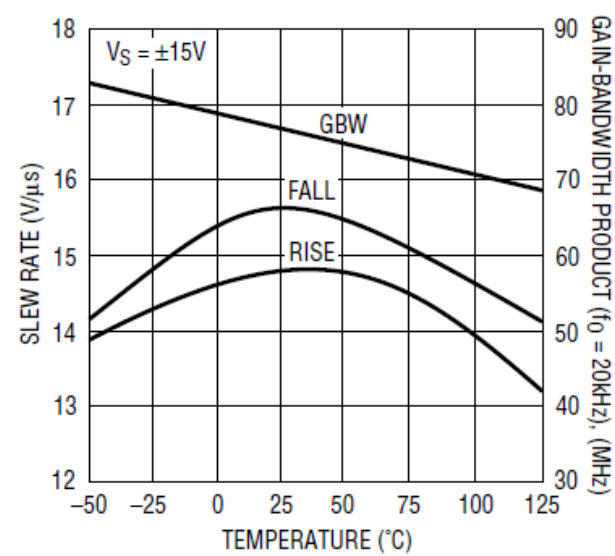


$$SR = \left. \frac{dV_o}{dt} \right|_{max} = \frac{I_{max}}{C}$$

Typical values are 1 V/ $\mu$ s – 100 V/ $\mu$ s or more



# Slew rate (large signal response)





$$V_o = V_M \sin(\omega t)$$

$$\left. \frac{dV_o}{dt} \right|_{max} = \omega V_M < SR$$

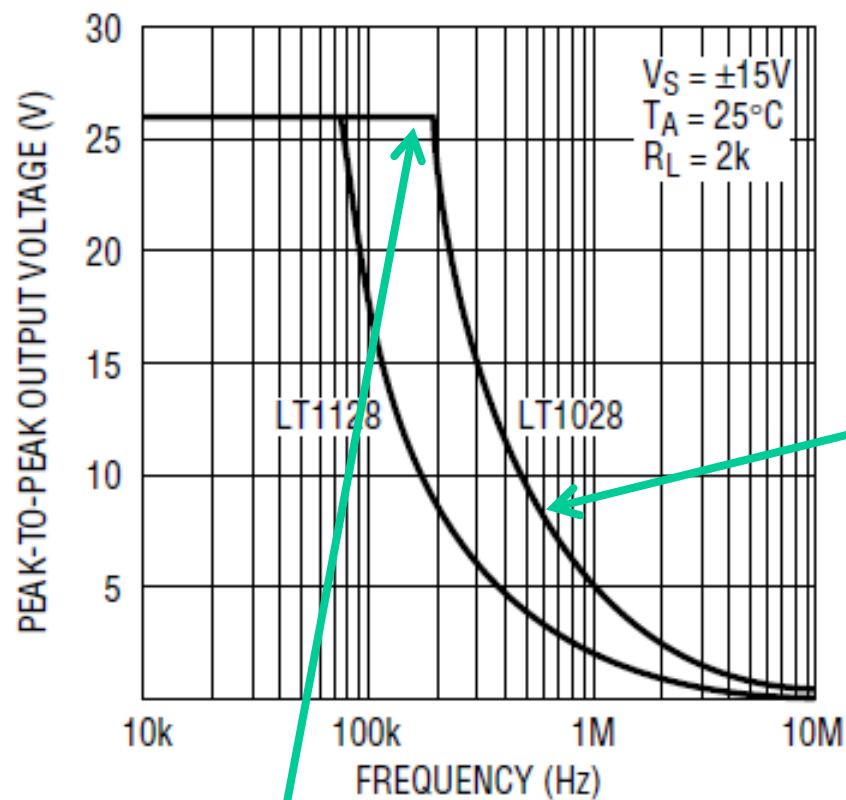
The OA can work at the maximum swing,  $V_o^{max}$ , without being limited by  $SR$  if

$$f \leq \frac{SR}{2\pi V_o^{max}} = FPBW$$



# Full-power bandwidth

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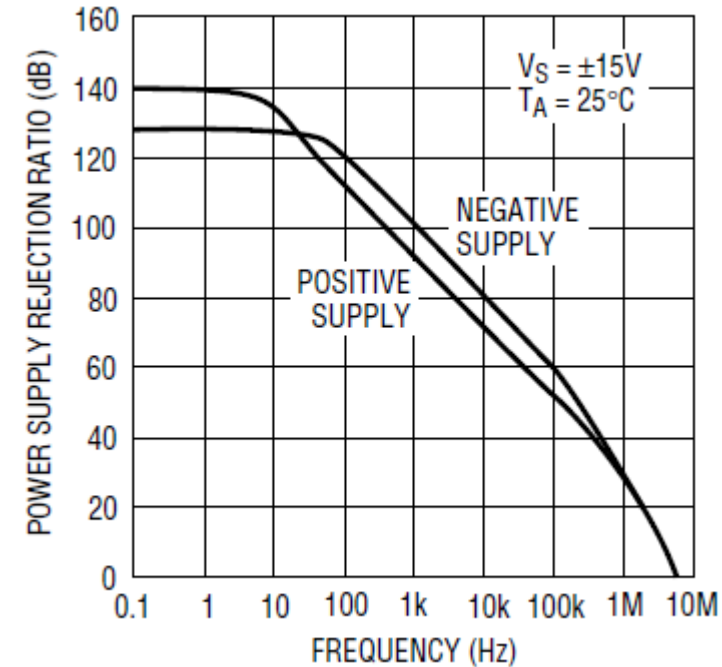
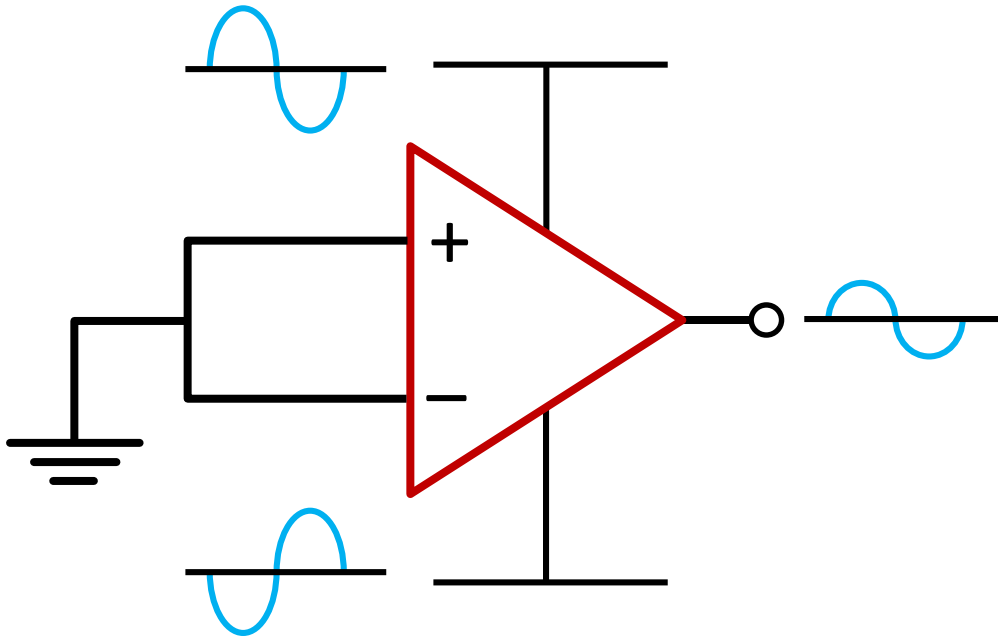
$$2\pi f V_o = SR$$

$$FPBW = \frac{SR}{2\pi V_o^{max}}$$



# Power supply rejection ratio

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- PSRR is the ratio between the PS disturbs and the differential signal that gives the same output
- Typical values are 80 – 100 dB (decreasing at high frequency)



- Differential signals and CMRR
- Instrumentation amplifiers
- Other OA limitations
- **Circuit simulation with Simulink**
- Appendix 1: Single-supply OA circuits
- Appendix 2: OA datasheets



- Numerical simulation is always used to refine the initial draft project
- Many tools are available, supporting all stages of the design process for both ICs and discretes
- Here we will briefly discuss how to use Simulink (a Matlab tool) to simulate our circuits
  - Matlab is freely available to PoliMI students



- To start a new project:
  - Matlab  $\Rightarrow$  Simulink  $\Rightarrow$  New  $\Rightarrow$  From Template  $\Rightarrow$  Model  $\Rightarrow$  Simscape  $\Rightarrow$  Electrical
- To add a component:
  - Library Browser  $\Rightarrow$  Simscape
    - Foundation Library  $\Rightarrow$  Electrical
    - Electrical



# Library content

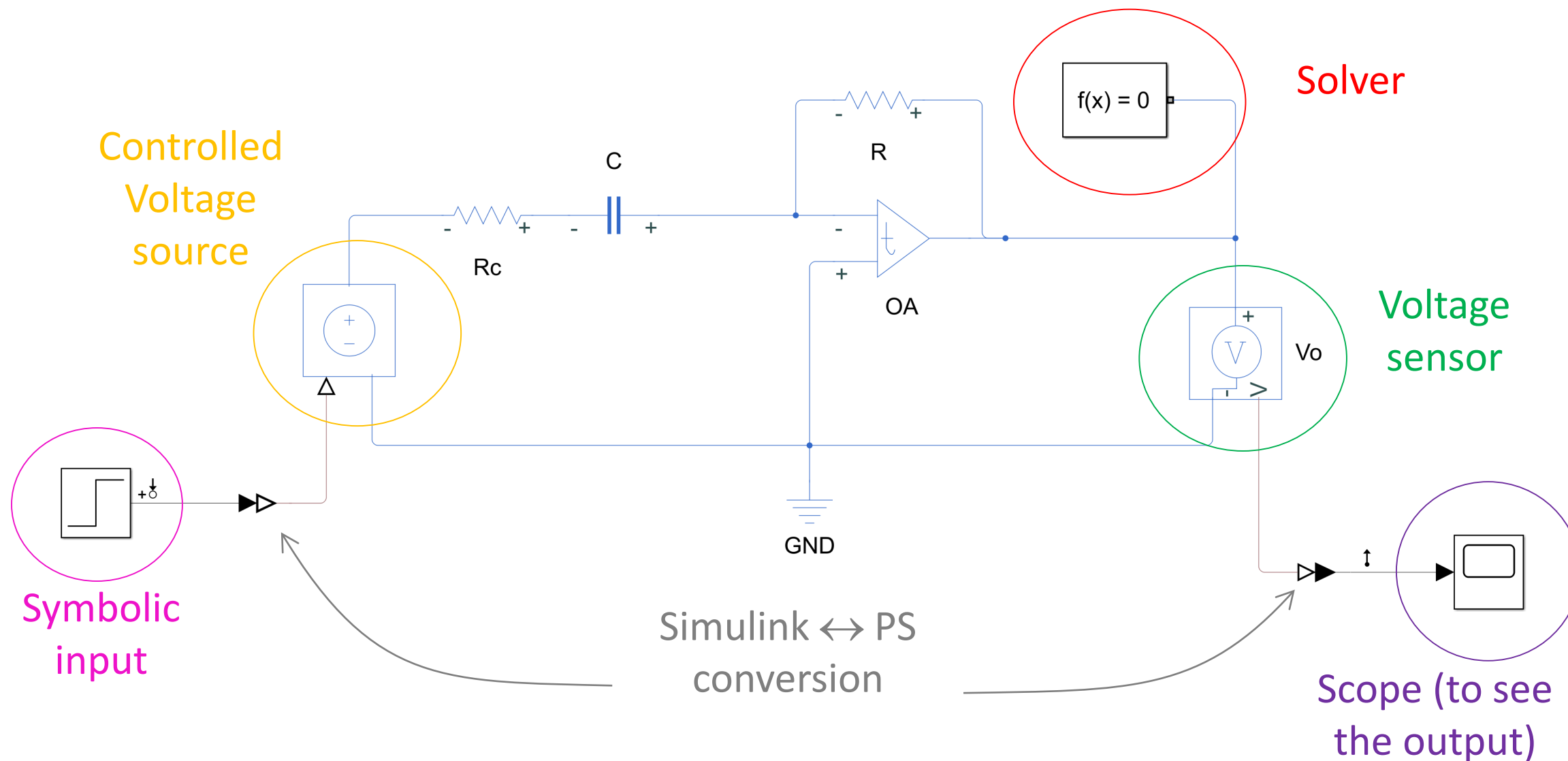
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| Library                                     | Main Submenu        | Main Content  |
|---|---------------------|---|
| Foundation Library $\Rightarrow$ Electrical | Electrical Sources  | AC/DC V/I sources, controlled V/I sources                                       |
|   | Electrical Elements | R, L, C, ground, ideal OA   |
|   | Electrical Sensors  | V/I sensors   |
| Electrical                                  | Sources             | Positive/negative supply rails, piecewise linear V/I sources, pulse V/I sources |
|   | Passive             | R, L, C, and more...  |
|   | Integrated Circuits | Band-limited OA, Fully-differential OA, logic                                   |



# Typical circuit (taken from Drill #2)

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- Start the linearization tool:
  - APPS (or Linearization)  $\Rightarrow$  Model Linearizer  $\Rightarrow$ 
    - Step
    - Bode
    - Impulse
- Note: this performs a **linear analysis**  $\Rightarrow$  non-linear effects such as those resulting from slew-rate, output voltage saturation and so on are NOT included



# Non-linear analysis (transient)

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- Replace the input with – say – a piecewise linear V/I source (no conversion needed) and set its parameters
- Set the simulation time and click **Run**
- Double-click on the **Scope** to see the output

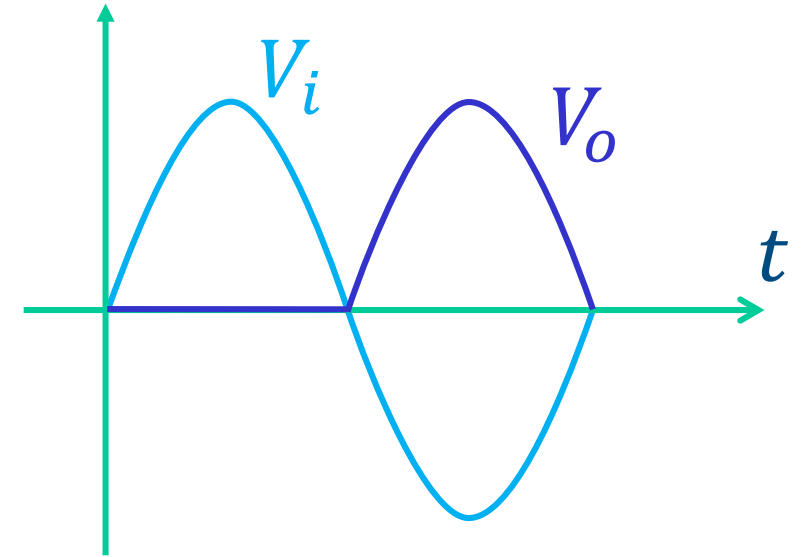
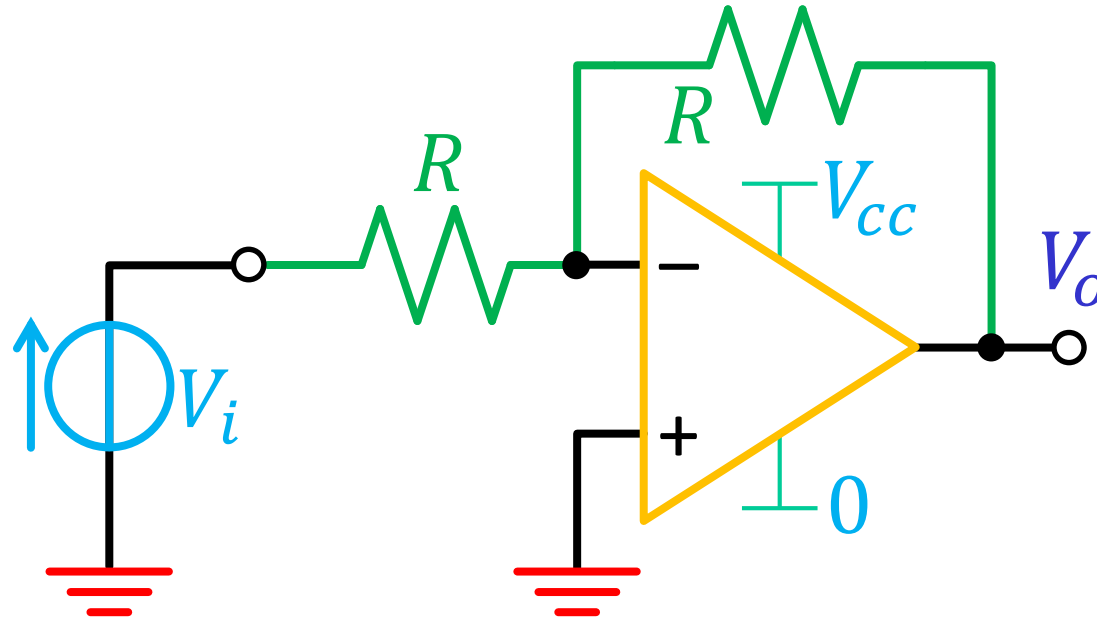


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# Example: inverting amplifier

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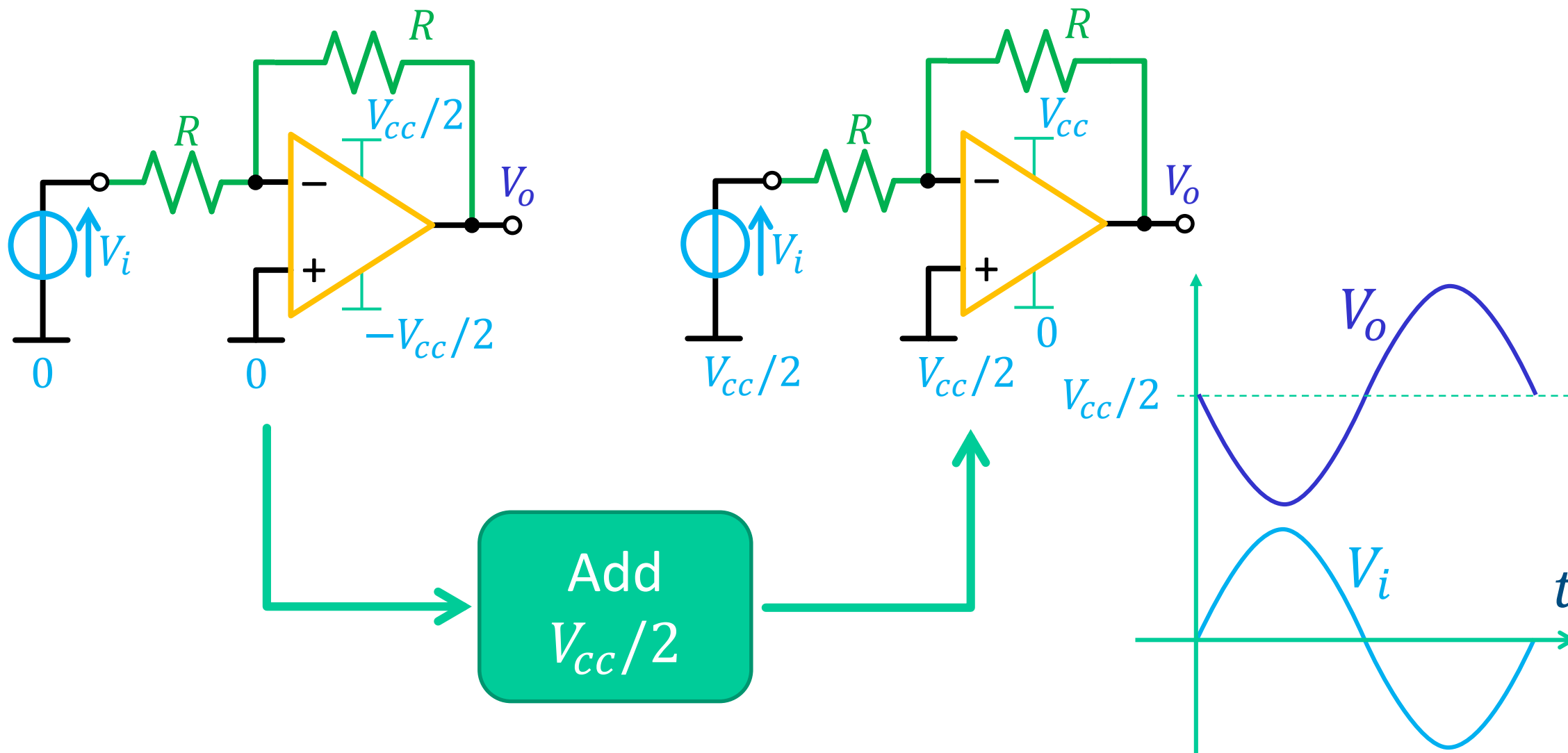


- $V_o$  cannot drop below the lower power supply
- Even negative values of  $V_i$  can undermine proper operation
- A new voltage reference point must be chosen for single-supply operation



# Voltage reference point

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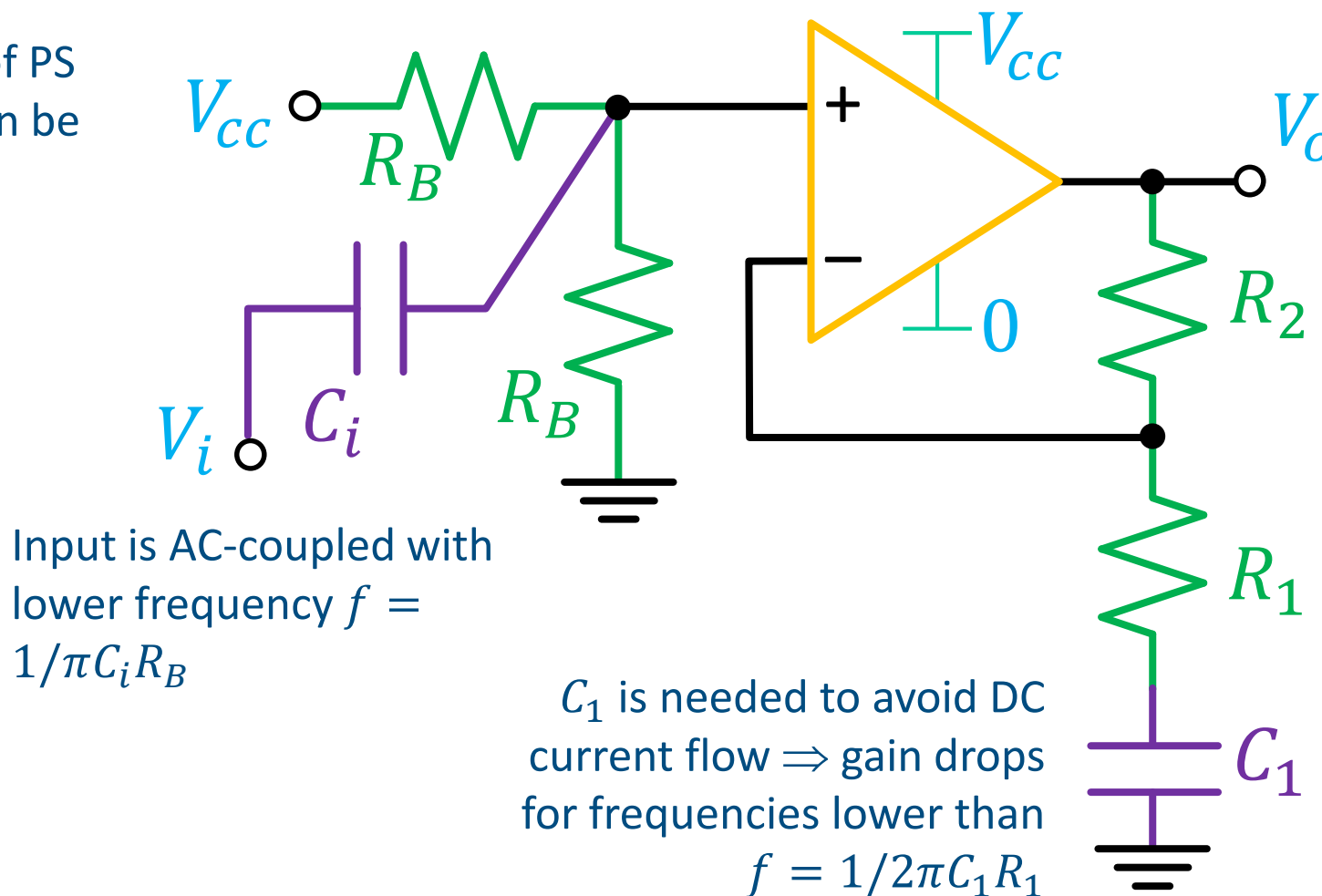




# Actual scheme (non-inverting amplifier)

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Rejection of PS disturbs can be an issue

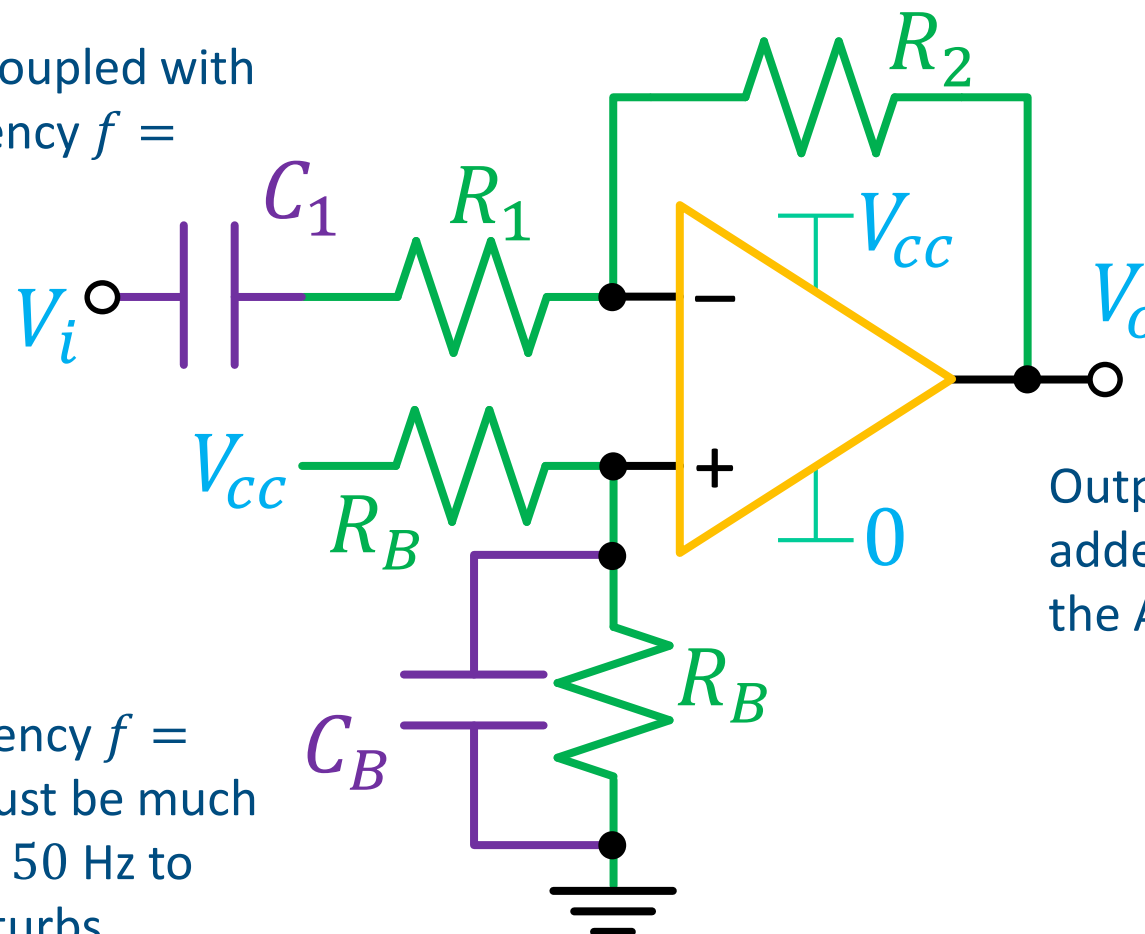




# Actual scheme (inverting amplifier)

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Input is AC-coupled with  
lower frequency  $f =$   
 $1/2\pi C_1 R_1$



Output capacitor can be  
added if interested in  
the AC signal only

Cutoff frequency  $f =$   
 $1/\pi C_B R_B$  must be much  
smaller than 50 Hz to  
reject PS disturbs

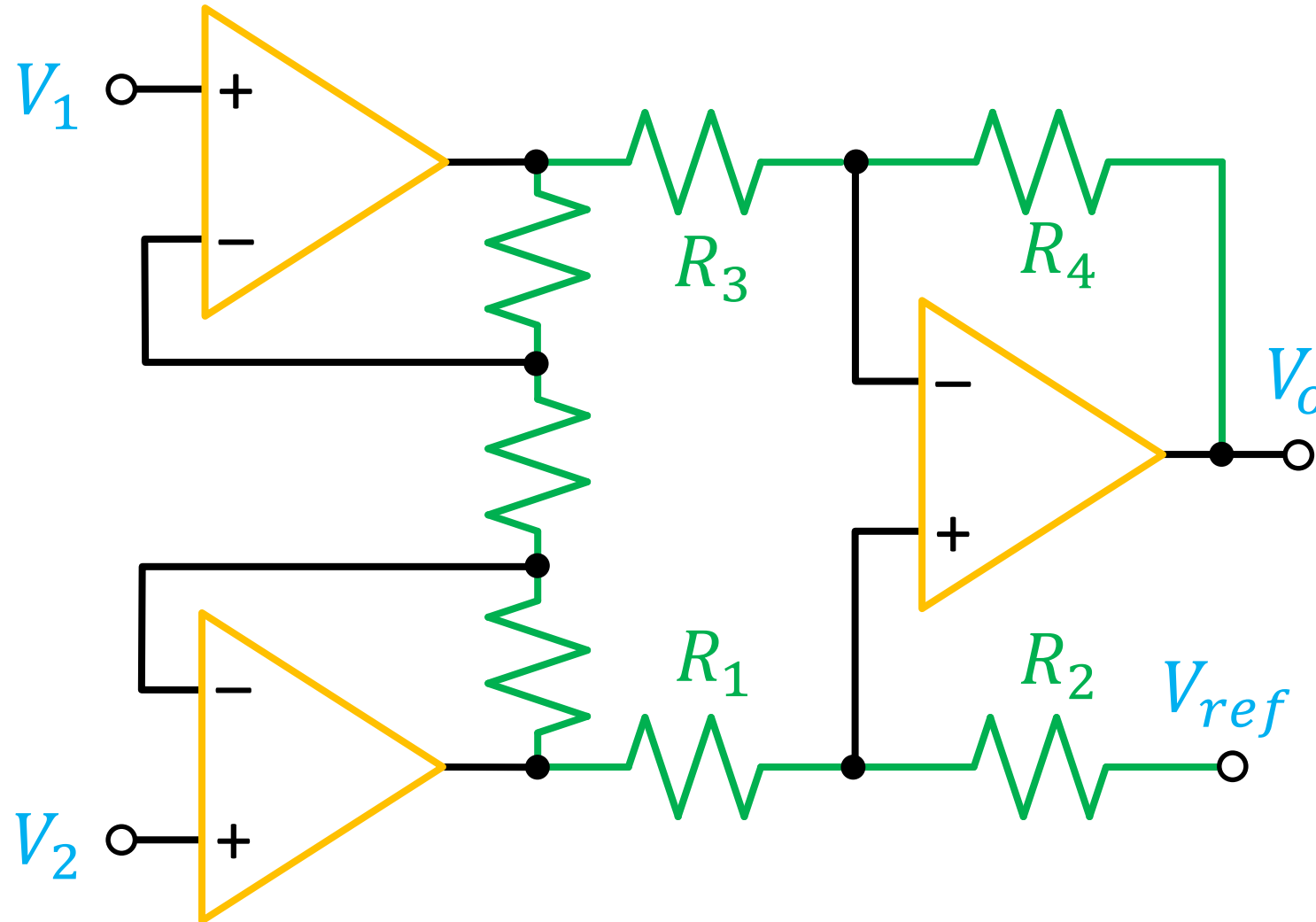


- $R_B$  should minimize power dissipation (high values) and bias/offset current errors (low values)
- Zener-diode biasing or linear voltage regulators are often used to provide the  $V_{CC}/2$  reference
- In the NI scheme, the input can be decoupled to the  $V_{CC}/2$  reference via an additional resistor and capacitor (see [3] for discussion)



# Single-supply INA

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An additional input is provided, which sets the reference output voltage. This is usually grounded for dual-supply operation, but should be set at around  $V_{cc}/2$  for single supply



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# OA datasheets

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## Low Noise, Precision Operational Amplifier

### FEATURES

- Low noise: 80 nV p-p (0.1 Hz to 10 Hz), 3 nV/√Hz
- Low drift: 0.2 μV/°C
- High speed: 2.8 V/μs slew rate, 8 MHz gain bandwidth
- Low  $V_{OS}$ : 10 μV
- Excellent CMRR: 126 dB at VCM of 11 V
- High open-loop gain: 1.8 million
- PinOP07, 3334A sockets
- Available in 8-pin

### GENERAL DESCRIPTION

The OP27 precision operational amplifier combines the low offset and drift of the OP07 with both high speed and low noise. Offset down to 25 μV and maximum drift of 0.6 μV/°C make the OP27 ideal for precision instrumentation applications. Exceptionally low noise,  $e_n = 3.5$  nV/√Hz, at 10 Hz, a low 1/f noise corner frequency of 2.7 Hz and high gain (1.8 million), a low accurate high-gain amplification of low-level signals. A gain-bandwidth product of 8 MHz and 2.8 V/μs slew rate provide excellent dynamic accuracy in high speed, data-acquisition systems.

A low input bias current of ±10 nA is achieved by use of a bias current cancellation circuit. Over the military temperature range this circuit typically holds  $I_{B1}$  and  $I_{B2}$  to ±20 nA and 15 nA, respectively.

The output stage has a high load driving capability. A guaranteed swing of ±10 V into 600 Ω and low output distortion make the OP27 an excellent choice for professional audio applications.

(Continued on page 3)

### FUNCTIONAL BLOCK DIAGRAM

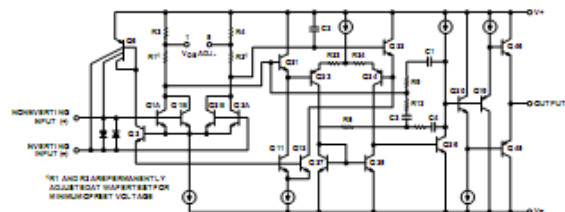


Figure 2

Rev. F

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### PIN CONFIGURATIONS

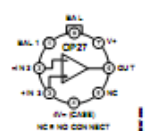


Figure 3 8-Lead TO-99-2 (Suff.)



Figure 2 8-Lead CERDIP - Gull Wing (Suff.),  
8-Lead PDIP (Suff.),  
8-Lead SOIC (Suff.)

## OP27

### SPECIFICATIONS

#### ELECTRICAL CHARACTERISTICS

$V_S = \pm 15$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

| Parameter  | Symbol               | Conditions                         | Min   | Typ   | Max   | Min   | Typ | Max | Unit   |
|--|----------------------|------------------------------------|-------|-------|-------|-------|-----|-----|--------|
| INPUT OFFSET VOLTAGE <sup>1</sup>                  | $V_{OS}$             |                                    | 10    | 25    | 30    | 30    | 100 |     | μV     |
| LONG-TERM $V_{OS}$ STABILITY <sup>2</sup>          | $V_{OS}/\text{Time}$ |                                    | 0.2   | 1.0   | 0.4   | 2.0   |     |     | μV/Mo  |
| INPUT OFFSET CURRENT <sup>3</sup>                  | $I_{OS}$             |                                    | 7     | 35    | 12    | 75    |     |     | nA     |
| INPUT BIAS CURRENT <sup>3</sup>                    | $I_B$                |                                    | ±10   | ±40   | ±15   | ±80   |     |     | nA     |
| INPUT NOISE VOLTAGE <sup>4</sup>                   | $e_n$                | 0.1 Hz to 10 Hz                    | 0.08  | 0.18  | 0.09  | 0.25  |     |     | μV p-p |
| INPUT NOISE<br>Voltage Density <sup>4</sup>        | $e_n$                | $f_c = 10$ Hz                      | 3.5   | 5.5   | 3.8   | 8.0   |     |     | nV/√Hz |
|  |                      | $f_c = 30$ Hz                      | 3.1   | 4.5   | 3.3   | 5.6   |     |     | nV/√Hz |
|  |                      | $f_c = 1000$ Hz                    | 3.0   | 3.8   | 3.2   | 4.5   |     |     | nV/√Hz |
| INPUT NOISE<br>Current Density <sup>4</sup>        | $i_n$                | $f_c = 10$ Hz                      | 1.7   | 4.0   | 1.7   |       |     |     | pA/√Hz |
|  |                      | $f_c = 30$ Hz                      | 1.0   | 2.3   | 1.0   |       |     |     | pA/√Hz |
|  |                      | $f_c = 1000$ Hz                    | 0.4   | 0.6   | 0.4   | 0.6   |     |     | pA/√Hz |
| INPUT RESISTANCE<br>Differential Mode <sup>5</sup> | $R_{in}$             |                                    | 1.3   | 6     | 0.7   | 4     |     |     | MΩ     |
| Common Mode <sup>5</sup>                           | $R_{inCM}$           |                                    | 3     | 3     | 2     | 2     |     |     | GΩ     |
| INPUT VOLTAGE RANGE                                | $V_{IR}$             |                                    | ±11.0 | ±12.3 | ±11.0 | ±12.3 |     |     | V      |
| COMMON-MODE REJECTION RATIO                        | $CMRR$               | $V_{OS} = \pm 11$ V                | 114   | 128   | 100   | 120   |     |     | dB     |
| POWER SUPPLY REJECTION RATIO                       | $PSRR$               | $V_{in} = \pm 4$ V to $\pm 18$ V   | 1     | 1.0   | 2     | 2.0   |     |     | μV/V   |
| LARGE SIGNAL VOLTAGE GAIN                          | $A_{v0}$             | $R_L = 2$ kΩ, $V_{OS} = \pm 10$ V  | 1000  | 1800  | 700   | 1500  |     |     | V/mV   |
|  |                      | $R_L = 600$ Ω, $V_{OS} = \pm 10$ V | 800   | 1500  | 600   | 1500  |     |     | V/mV   |
| OUTPUT VOLTAGE SWING                               | $V_o$                | $R_L = 2$ kΩ                       | ±12.0 | ±13.8 | ±11.5 | ±13.5 |     |     | V      |
|  |                      | $R_L = 600$ Ω                      | ±10.0 | ±11.5 | ±10.0 | ±11.5 |     |     | V      |
| SLEW RATE <sup>6</sup>                             | $SR$                 | $R_L = 2$ kΩ                       | 1.7   | 2.8   | 1.7   | 2.8   |     |     | V/μs   |
| GAIN-BANDWIDTH PRODUCT <sup>7</sup>                | $GBW$                |                                    | 5.0   | 8.0   | 5.0   | 8.0   |     |     | MHz    |
| OPEN-LOOP OUTPUT RESISTANCE                        | $R_o$                | $V_{OS} = 0$ , $I_B = 0$           | 70    |       | 70    |       |     |     | Ω      |
| POWER CONSUMPTION                                  | $P_D$                | $V_{OS}$                           | 90    | 140   | 100   | 170   |     |     | mW     |
| OFFSET ADJUSTMENT RANGE                            | $R_{offset}$         | $R_{offset} = 10$ kΩ               | ±40   |       | ±40   |       |     |     | mV     |

<sup>1</sup> Input offset voltage measurements are performed approximately 0.5 seconds after application of power. A/grade dequaranteed fully warmed up.

<sup>2</sup> Long-term input offset voltage stability refers to the average drift of  $V_{OS}$  over the extended period of time for the first 100 days of operation. Excluding the initial four-hour operation, changes in  $V_{OS}$  during the first 30 days are typically 1.5 μV (refer to the Typical Performance Characteristics section).

<sup>3</sup> Sample tested.

<sup>4</sup> See voltage noise test circuit (Figure 21).

<sup>5</sup> Guaranteed by input bias current.

<sup>6</sup> Guaranteed by design.

## OP27

### TYPICAL PERFORMANCE CHARACTERISTICS

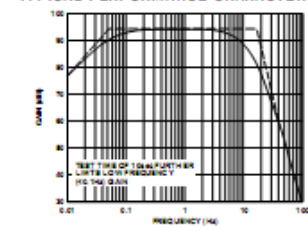


Figure 4. 0.1 Hz to 10 Hz p-p Noise Test Frequency Response

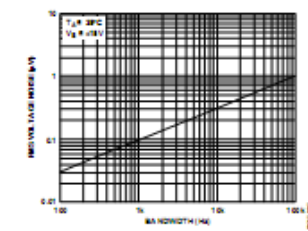


Figure 7. Input Wideband Voltage Noise Density vs. Frequency (0.1 Hz to 1000 Hz)

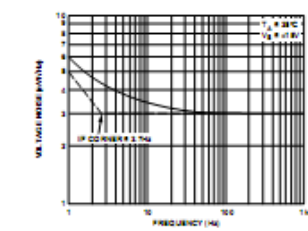


Figure 5. Voltage Noise Density vs. Frequency

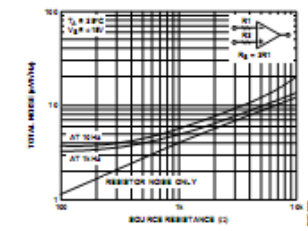


Figure 8. Total Noise vs. Source Resistance

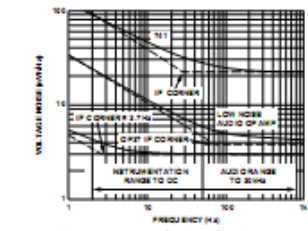


Figure 6. A Comparison of Op Amp Voltage Noise Spectra

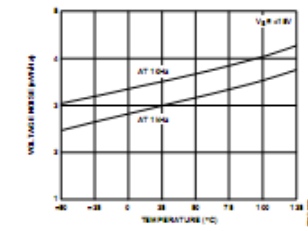


Figure 9. Voltage Noise Density vs. Temperature



- *Features & General description* (sometimes with *Block diagram*, *Schematic* and *Applications*)
- *Absolute maximum ratings*
- *Electrical characteristics*
- *Typical performance characteristics*
- Other info (dimensions, package and ordering info, etc.)



# Features/Description

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## LM158-LM258-LM358

Low power dual operational amplifiers

### Features

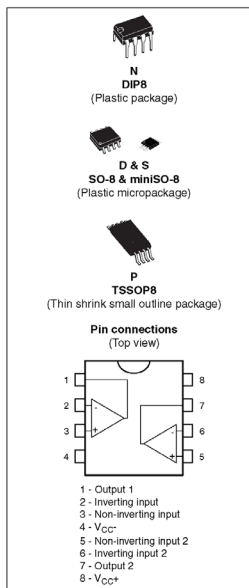
- Internally frequency-compensated
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)
- Very low supply current per operator essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)
- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common-mode voltage range includes negative rails
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to ( $V_{CC}^+ - 1.5V$ )

### Description

These circuits consist of two independent, high-gain, internally frequency-compensated op-amps, which are specifically designed to operate from a single power supply over a wide range of voltages. The low-power supply drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op-amp circuits, which can now be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard +5 V, which is used in logic systems and will easily provide the required interface electronics with no additional power supply.

In linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.



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Rev 8

[www.st.com](http://www.st.com)



## LT1028/LT1128

Ultralow Noise Precision High Speed Op Amps

### FEATURES

- Voltage Noise  
1.1nV/ $\sqrt{\text{Hz}}$  Max at 1kHz  
0.85nV/ $\sqrt{\text{Hz}}$  Typ at 1kHz  
1.0nV/ $\sqrt{\text{Hz}}$  Typ at 10Hz  
35nV<sub>P-P</sub> Typ, 0.1Hz to 10Hz
- Voltage and Current Noise 100% Tested
- Gain-Bandwidth Product  
LT1028: 50MHz Min  
LT1128: 13MHz Min
- Slew Rate  
LT1028: 11V/ $\mu\text{s}$  Min  
LT1128: 5V/ $\mu\text{s}$  Min
- Offset Voltage: 40 $\mu\text{V}$  Max
- Drift with Temperature: 0.8 $\mu\text{V}/^\circ\text{C}$  Max
- Voltage Gain: 7 Million Min
- Available in 8-Pin SO Package

### APPLICATIONS

- Low Noise Frequency Synthesizers
- High Quality Audio
- Infrared Detectors
- Accelerometer and Gyro Amplifiers
- 350 $\Omega$  Bridge Signal Conditioning
- Magnetic Search Coil Amplifiers
- Hydrophone Amplifiers

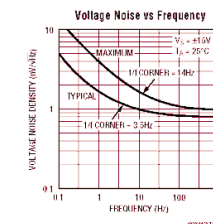
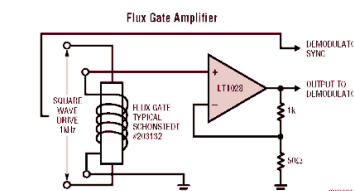
### DESCRIPTION

The LT<sup>®</sup>1028 (gain of -1 stable)/LT1128 (gain of +1 stable) achieve a new standard of excellence in noise performance with 0.85nV/ $\sqrt{\text{Hz}}$  1kHz noise, 1.0nV/ $\sqrt{\text{Hz}}$  10Hz noise. This ultralow noise is combined with excellent high speed specifications (gain-bandwidth product is 75MHz for LT1028, 20MHz for LT1128), distortion-free output, and true precision parameters (0.1 $\mu\text{V}/^\circ\text{C}$  drift, 10 $\mu\text{V}$  offset voltage, 30 million voltage gain). Although the LT1028/LT1128 input stage operates at nearly 1mA of collector current to achieve low voltage noise, input bias current is only 25nA.

The LT1028/LT1128's voltage noise is less than the noise of a 50 $\Omega$  resistor. Therefore, even in very low source impedance transducer or audio amplifier applications, the LT1028/LT1128's contribution to total system noise will be negligible.

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### TYPICAL APPLICATION



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- General purpose
- High speed
- Precision
- Low bias current
- Low noise
- Low power
- Other (zero drift, rail-to-rail, high voltage, high output current,...)



## OP275

### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

|   |       |                 |
|---|-------|-----------------|
| Supply Voltage                                    | ..... | ±22 V           |
| Input Voltage <sup>2</sup>                        | ..... | ±22 V           |
| Differential Input Voltage <sup>2</sup>           | ..... | ±7.5 V          |
| Output Short-Circuit Duration to GND <sup>3</sup> | ..... | Indefinite      |
| Storage Temperature Range                         |       |                 |
| P, S Packages                                     | ..... | –65°C to +150°C |
| Operating Temperature Range                       |       |                 |
| OP275G  | ..... | –40°C to +85°C  |
| Junction Temperature Range                        |       |                 |
| P, S Packages                                     | ..... | –65°C to +150°C |
| Lead Temperature Range (Soldering, 60 sec)        | ..... | 300°C           |

| Package Type           | $\theta_{JA}$ <sup>4</sup> | $\theta_{JC}$ | Unit |
|------------------------|----------------------------|---------------|------|
| 8-Lead Plastic DIP (P) | 103                        | 43            | °C/W |
| 8-Lead SOIC (S)        | 158                        | 43            | °C/W |

### NOTES

<sup>1</sup>Absolute maximum ratings apply to packaged parts, unless otherwise noted.

<sup>2</sup>For supply voltages greater than ±22V, the absolute maximum input voltage is equal to the supply voltage.

<sup>3</sup>Shorts to either supply may destroy the device. See data sheet for full details.

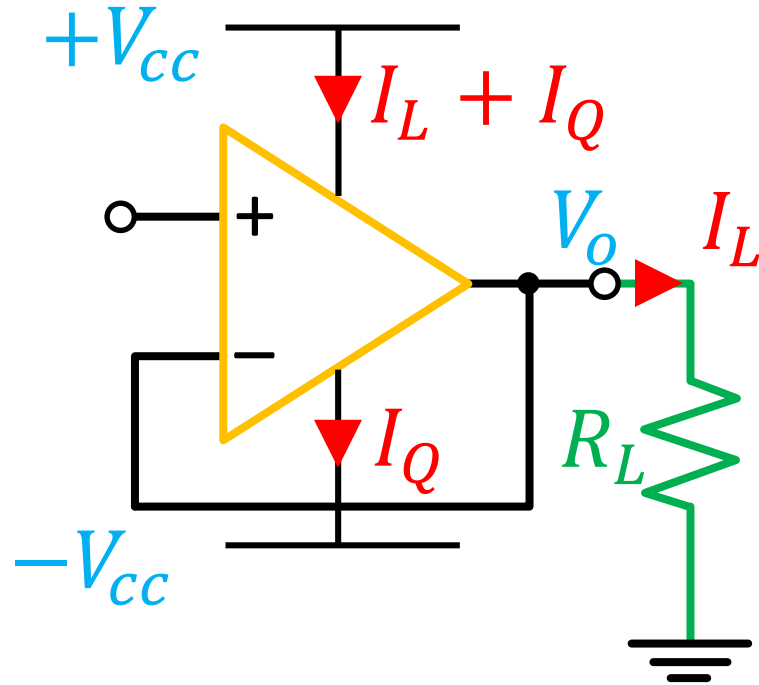
<sup>4</sup> $\theta_{JA}$  is specified for the worst-case conditions, i.e.,  $\theta_{JA}$  is specified for device in socket for PDIP packages;  $\theta_{JA}$  is specified for device soldered in circuit board for SOIC packages.

AMRs are the maximum values of few key parameters that the OA can safely tolerate. Operation beyond them leads to permanent damage



# Power dissipation calculation

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$$P_{R_L} = V_o I_L$$

$$P_{OA} = 2V_{cc}I_Q + (V_{cc} - V_o)I_L$$

Example:  $V_{cc} = 10 \text{ V}$ ,  $V_o = 2 \text{ V}$ ,  $R_L = 500 \Omega \Rightarrow I_L = 4 \text{ mA}$

$$P_{R_L} = 8 \text{ mW}, P_{OA} \approx 32 \text{ mW}$$

- $I_Q$  is a quiescent current always flowing when the OA is powered. Indicative values are  $0.5 \mu\text{A} - 0.5 \text{ mA}$
- Do not confuse it with the **supply current** (its maximum value)



- The increase in junction temperature limits the power dissipation

$$P_{max} = \frac{T_{Jmax} - T_A}{\theta_{JA}}$$

- Data from previous sheet:  $T_{Jmax} = 150^{\circ}\text{C}$ ,  $\theta_{JA} = 103^{\circ}\text{C/W}$ . For  $T_A = 25^{\circ}\text{C}$ ,  $P_{max} = 1.2 \text{ W}$
- **Power OAs** can reach several tens of W



**Table 2. Operating conditions**

| Symbol     | Parameter   | Value                                  | Unit |
|------------|---|--|------|
| $V_{CC}$   | Supply voltage  | 3 to 30                                | V    |
| $V_{icm}$  | Common mode input voltage range <sup>(1)</sup>                  | $V_{CC}^- - 0.3$ to $V_{CC}^+ - 1.5$   | V    |
| $T_{oper}$ | Operating free air temperature range<br>LM158<br>LM258<br>LM358 | -55 to +125<br>-40 to +105<br>0 to +70 | °C   |

1. When used in comparator, the functionality is guaranteed as long as at least one input remains within the operating common mode voltage range.

Simply, the intervals that guarantee that the OA works as specified



- Show the most important properties of the OA
- Typical, maximum and minimum values at the operating conditions are usually reported



# Example

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## LT1028/LT1128

### ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

| SYMBOL                           | PARAMETER  | CONDITIONS   | LT1028AM/AC<br>LT1128AM/AC |                          |                          | LT1028M/C<br>LT1128M/C |                          |                          | UNITS                                  |
|----------------------------------|--|--|----------------------------|--------------------------|--------------------------|------------------------|--------------------------|--------------------------|--|
|                                  |  |  | MIN                        | TYP                      | MAX                      | MIN                    | TYP                      | MAX                      |  |
| $V_{OS}$                         | Input Offset Voltage                                 | (Note 2)   |                            | 10                       | 40                       |                        | 20                       | 80                       | $\mu V$                                |
| $\frac{\Delta V_{OS}}{\Delta T}$ | Long Term Input Offset Voltage Stability             | (Note 3)   |                            | 0.3                      |                          |                        | 0.3                      |                          | $\mu V/Mo$                             |
| $I_{OS}$                         | Input Offset Current                                 | $V_{CM} = 0V$  |                            | 12                       | 50                       |                        | 18                       | 100                      | nA                                     |
| $I_B$                            | Input Bias Current                                   | $V_{CM} = 0V$  |                            | $\pm 25$                 | $\pm 90$                 |                        | $\pm 30$                 | $\pm 180$                | nA                                     |
| $e_n$                            | Input Noise Voltage                                  | 0.1Hz to 10Hz (Note 4)   |                            | 35                       | 75                       |                        | 35                       | 90                       | nV $\sqrt{Hz}$                         |
|                                  | Input Noise Voltage Density                          | $f_0 = 10Hz$ (Note 5)<br>$f_0 = 1000Hz$ , 100% tested  |                            | 1.00<br>0.85             | 1.7<br>1.1               |                        | 1.0<br>0.9               | 1.9<br>1.2               | nV $\sqrt{Hz}$<br>nV $\sqrt{Hz}$       |
| $I_n$                            | Input Noise Current Density                          | $f_0 = 10Hz$ (Note 4 and 6)<br>$f_0 = 1000Hz$ , 100% tested  |                            | 4.7<br>1.0               | 10.0<br>1.6              |                        | 4.7<br>1.0               | 12.0<br>1.8              | pA $\sqrt{Hz}$<br>pA $\sqrt{Hz}$       |
|                                  | Input Resistance<br>Common Mode<br>Differential Mode |  |                            | 300<br>20                |                          |                        | 300<br>20                |                          | M $\Omega$<br>k $\Omega$               |
|                                  | Input Capacitance                                    |  |                            | 5                        |                          |                        | 5                        |                          | pF                                     |
|                                  | Input Voltage Range                                  |  |                            | $\pm 11.0$               | $\pm 12.2$               |                        | $\pm 11.0$               | $\pm 12.2$               | V                                      |
| CMRR                             | Common Mode Rejection Ratio                          | $V_{CM} = \pm 11V$   |                            | 114                      | 126                      |                        | 110                      | 126                      | dB                                     |
| PSRR                             | Power Supply Rejection Ratio                         | $V_S = \pm 4V$ to $\pm 18V$  |                            | 117                      | 133                      |                        | 110                      | 132                      | dB                                     |
| $A_{VOL}$                        | Large-Signal Voltage Gain                            | $R_L \geq 2k$ , $V_O = \pm 12V$<br>$R_L \geq 1k$ , $V_O = \pm 10V$<br>$R_L \geq 600\Omega$ , $V_O = \pm 10V$ |                            | 7.0<br>5.0<br>3.0        | 30.0<br>20.0<br>15.0     |                        | 5.0<br>3.5<br>2.0        | 30.0<br>20.0<br>15.0     | V/ $\mu V$<br>V/ $\mu V$<br>V/ $\mu V$ |
| $V_{OUT}$                        | Maximum Output Voltage Swing                         | $R_L \geq 2k$<br>$R_L \geq 600\Omega$  |                            | $\pm 12.3$<br>$\pm 11.0$ | $\pm 13.0$<br>$\pm 12.2$ |                        | $\pm 12.0$<br>$\pm 10.5$ | $\pm 13.0$<br>$\pm 12.2$ | V<br>V                                 |
| SR                               | Slew Rate  | $A_{VOL} = -1$ LT1028<br>$A_{VOL} = -1$ LT1128   |                            | 11.0<br>5.0              | 15.0<br>6.0              |                        | 11.0<br>4.5              | 15.0<br>6.0              | V/ $\mu s$<br>V/ $\mu s$               |
| GBW                              | Gain-Bandwidth Product                               | $f_0 = 20kHz$ (Note 7) LT1028<br>$f_0 = 200kHz$ (Note 7) LT1128  |                            | 50<br>13                 | 75<br>20                 |                        | 50<br>11                 | 75<br>20                 | MHz<br>MHz                             |
| $Z_O$                            | Open-Loop Output Impedance                           | $V_O = 0$ , $I_O = 0$  |                            | 80                       |                          |                        | 80                       |                          | $\Omega$                               |
| $I_S$                            | Supply Current                                       |  |                            | 7.4                      | 9.5                      |                        | 7.6                      | 10.5                     | mA                                     |

Voltage and temperature are usually specified



1. <http://www.analog.com/media/en/technical-documentation/application-notes/AN-244.pdf>
2. <http://www.analog.com/en/education/education-library/dh-designers-guide-to-instrumentation-amps.html>
3. <http://www.analog.com/en/analog-dialogue/articles/avoiding-op-amp-instability-problems.html>